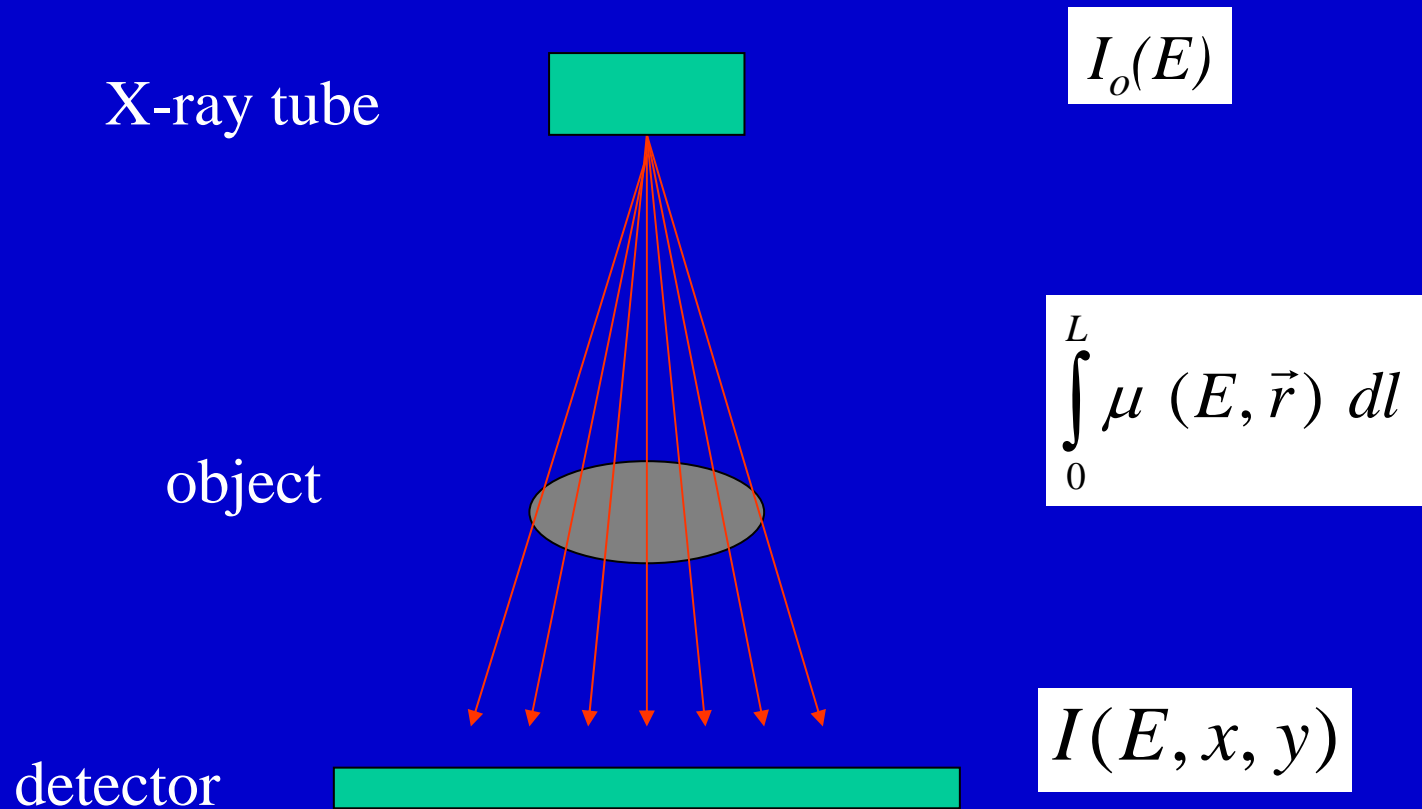


# Imaging Theory for X-Ray Pixel Detectors

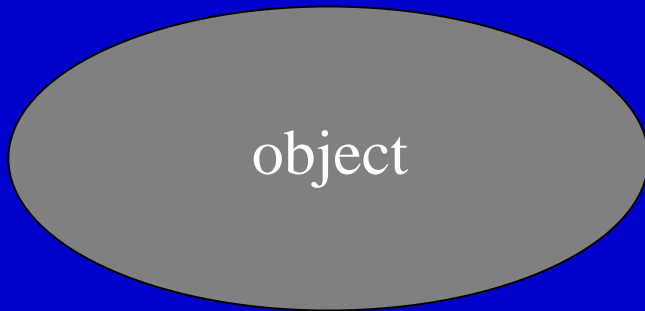
Gisela Anton  
University of Erlangen-Nürnberg  
IWORID 2005



# X-Ray Imaging Elements



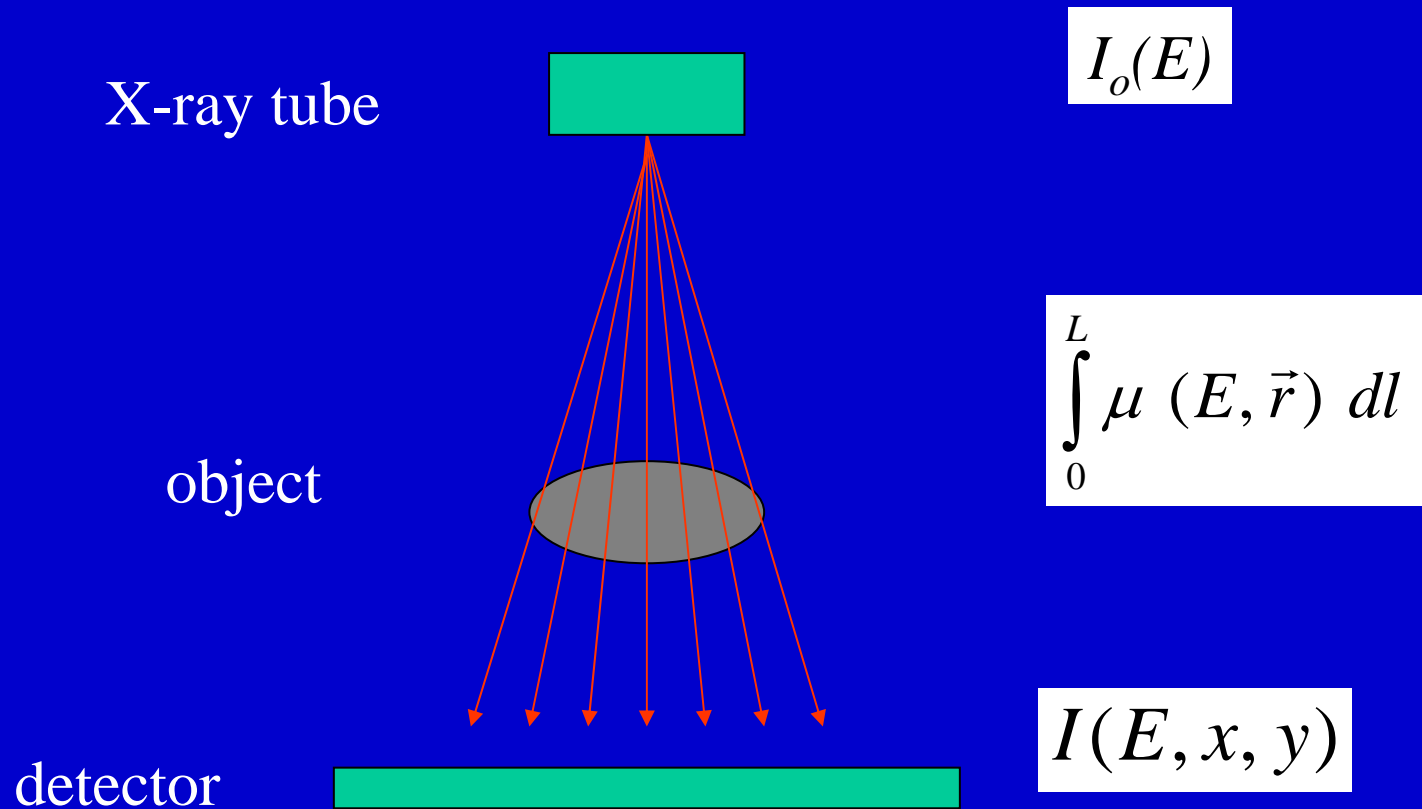
# X-Ray Image



$$\mu (E, \vec{r})$$

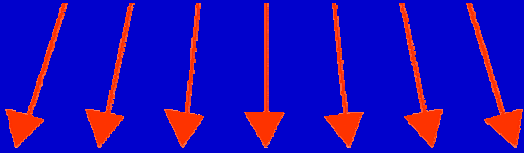
attenuation coefficient

# X-Ray Imaging Elements

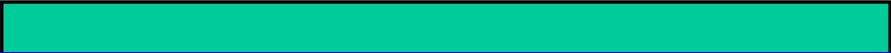


# Detector Transfer Function

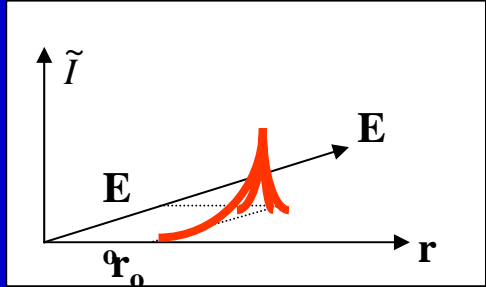
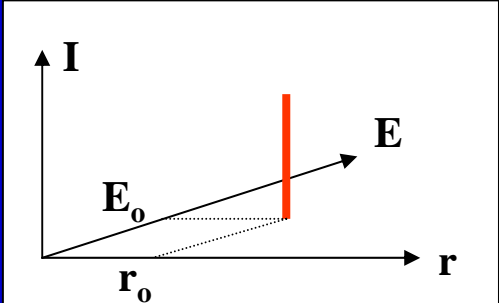
$$I(E_o, x_o, y_o)$$



detector



$$\tilde{I}(E, x, y)$$



# Tools

A. Simulation calculations:

→ ROSI (Erlangen)

B. Measurements:

→ Medipix 1 and 2

# Imaging modalities

- A. monoenergetic projective image
- B. spectral projective image
- C. tomographic image (3D)

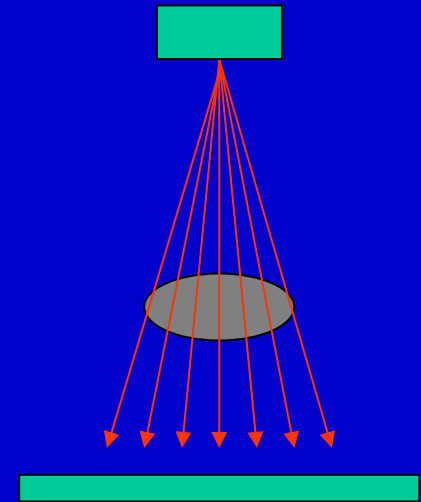
# A. Monoenergetic Projective Image

Intensity at detector position (x,y) :

$$I(x, y) = I_o e^{-\int_0^L \mu(\vec{r}) dl}$$

Image information at position (x,y) :

$$\begin{aligned} t(x, y) &= -\ln \frac{I(x, y)}{I_o} \\ &= \int_0^L \mu(\vec{r}) dl \end{aligned}$$



$$\mu = \mu(E)$$



# Aim: Visibility of Structures

Structure:  $I_1(x_1, y_1) \neq I_2(x_2, y_2)$

Detector requirements:

direct:

position resolution

p (first interaction)

intensity resolution

c = max

indirect:

pixel size:

$\rightarrow 0$

detection efficiency

$\varepsilon=1$

high dynamic range

0, inf

low noise

noise = 0

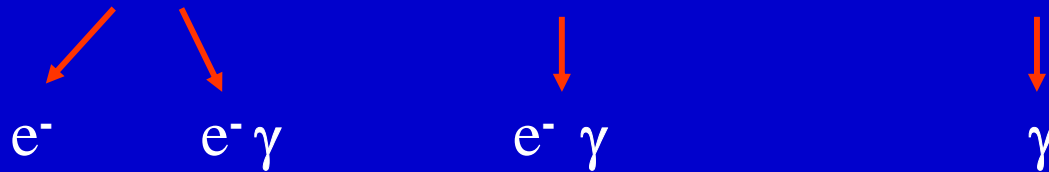
# Position resolution

ideal: measure point of first interaction with infinite resolution

real: 1) physics of X-Ray interaction with sensor material

first interaction:

photoabsorption. Compton scattering, Rayleigh scattering



secondary interactions:

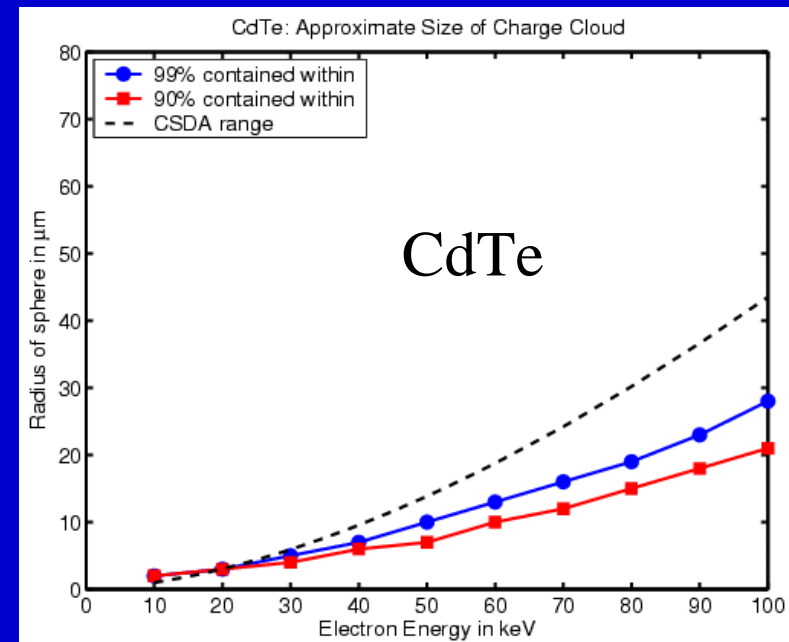
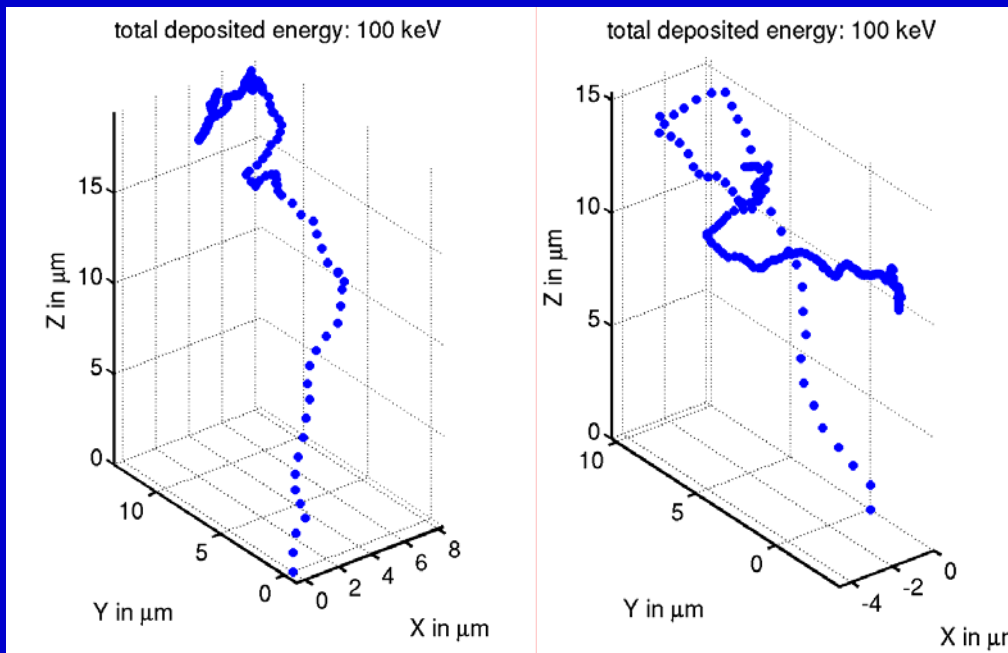
electrons:  $dE/dx$ , photons: photoabs., Compton, Rayleigh

2) propagation of charges (scin.photons)

3) finite size of sensor (read out) pixels

# 1) physics of X-Ray interaction with sensor material

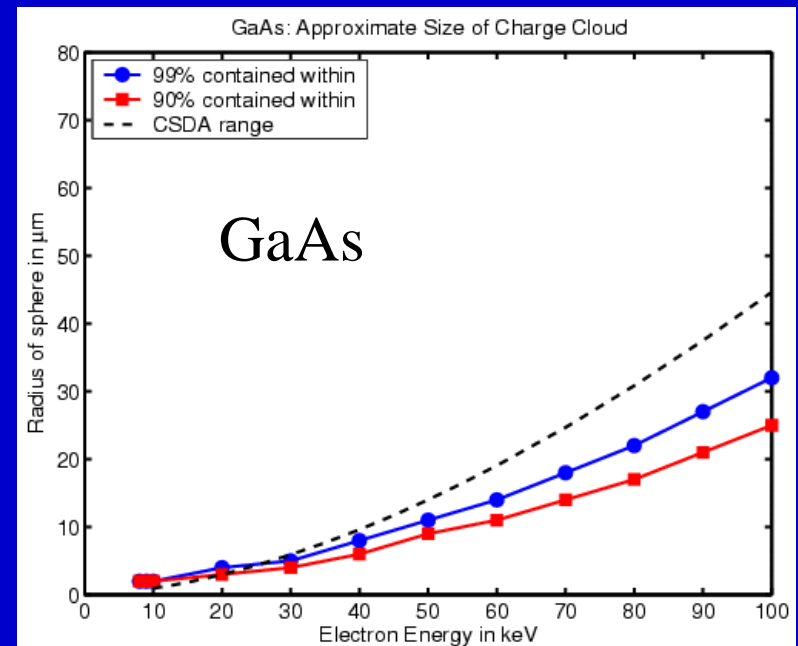
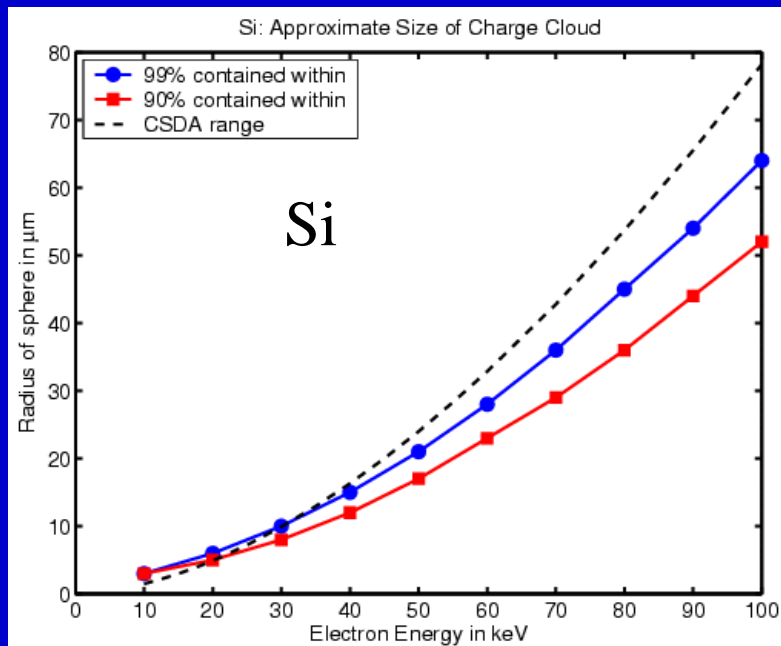
## Propagation of electrons:



Electron 90%energy range:  $< 20 \mu\text{m}$  for  $E < 100 \text{ keV}$  in CdTe

# 1) physics of X-Ray interaction with sensor material

## Propagation of electrons:

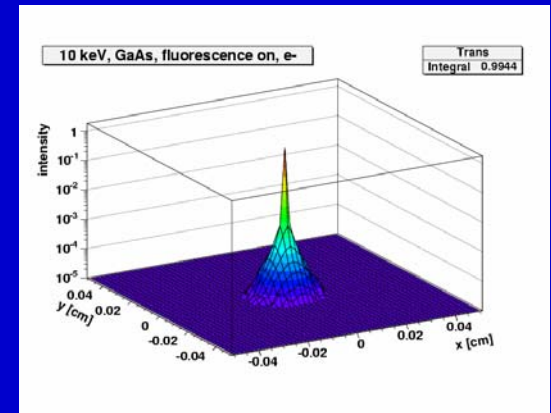
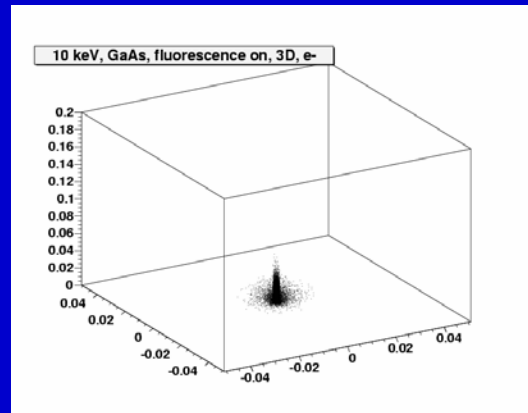


Electron 90% energy range:  $< 50 \mu\text{m}$  for  $E < 100 \text{ keV}$  in Si

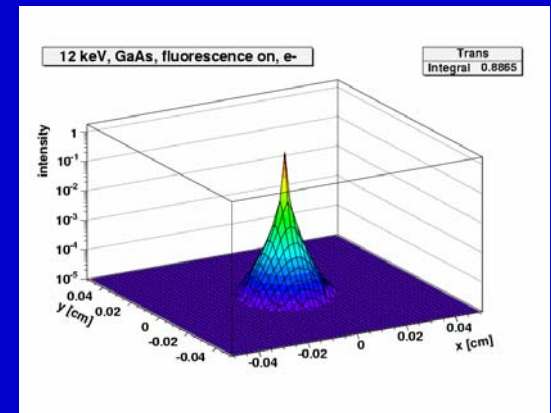
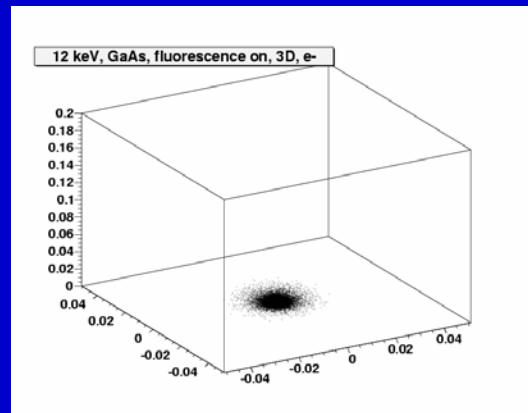
# 1) physics of X-Ray interaction with sensor material

## Propagation of secondary photons:

GaAs  
10 keV

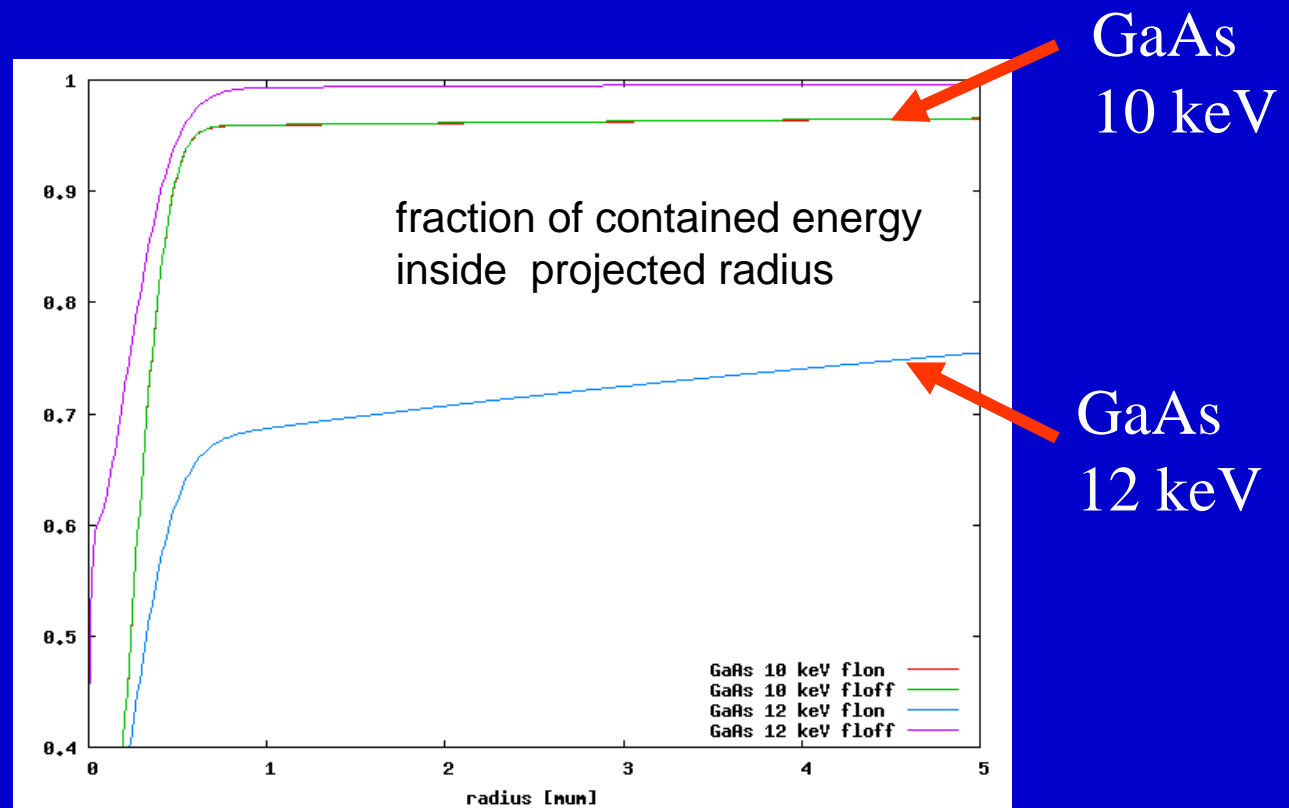


GaAs  
12 keV



# 1) physics of X-Ray interaction with sensor material

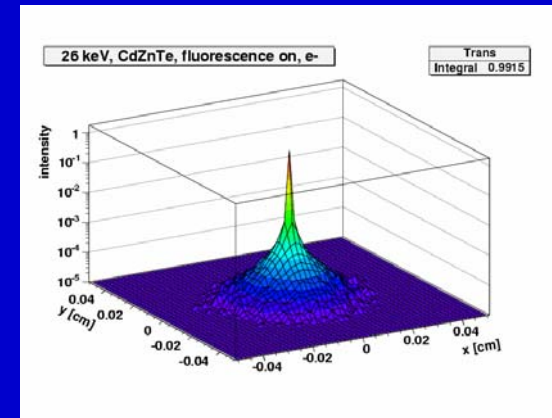
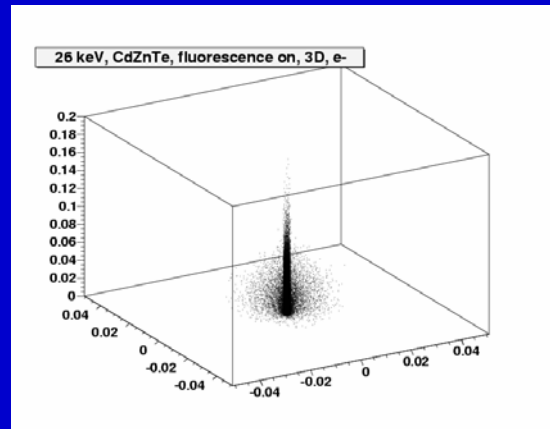
Propagation of secondary photons:



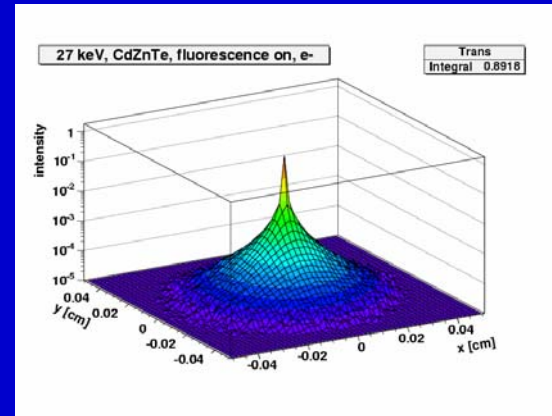
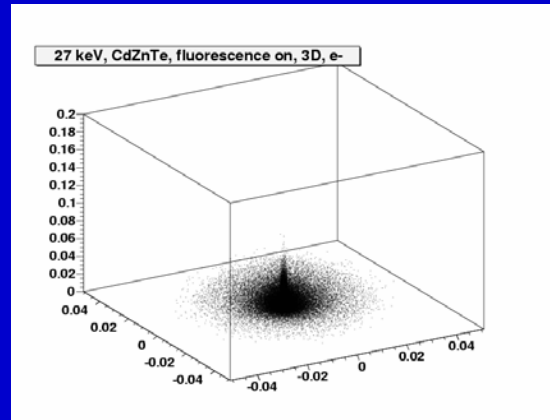
# 1) physics of X-Ray interaction with sensor material

## Propagation of secondary photons:

CZT  
26 keV

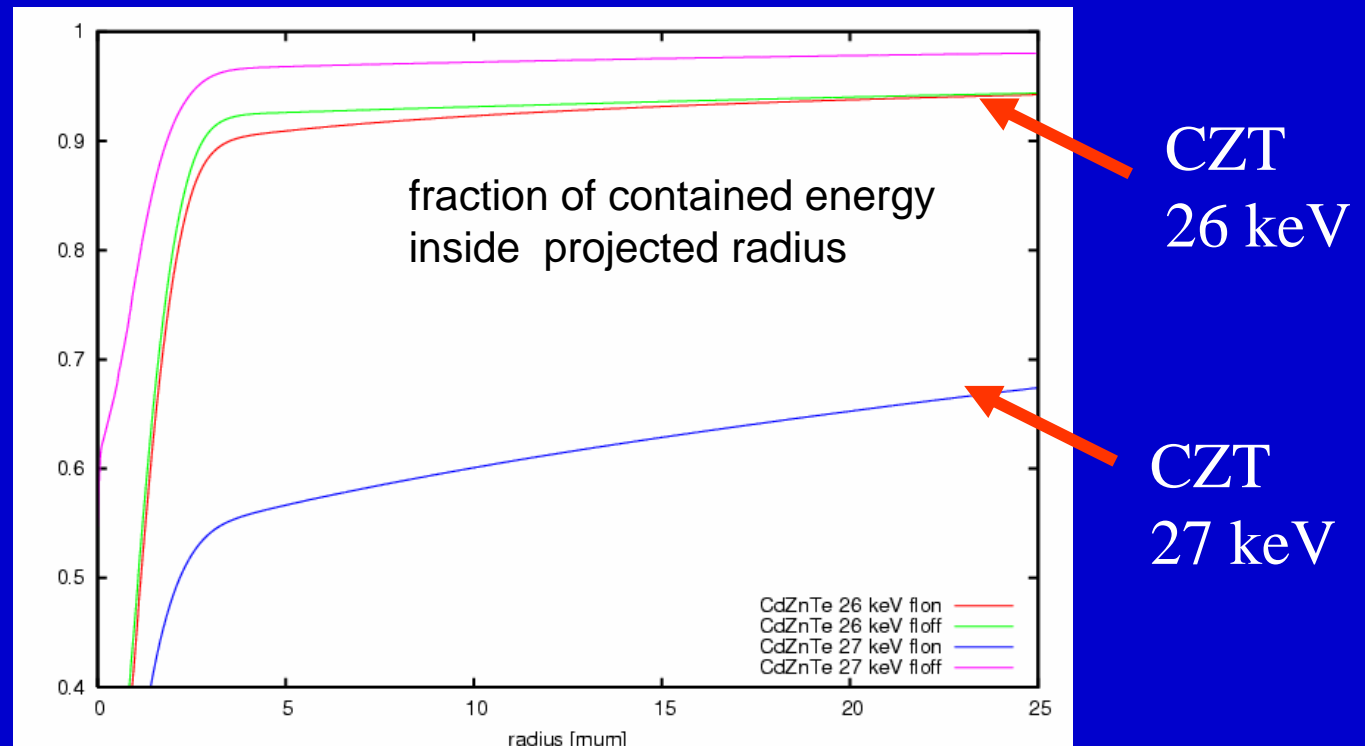


CZT  
27 keV



# 1) physics of X-Ray interaction with sensor material

Propagation of secondary photons:

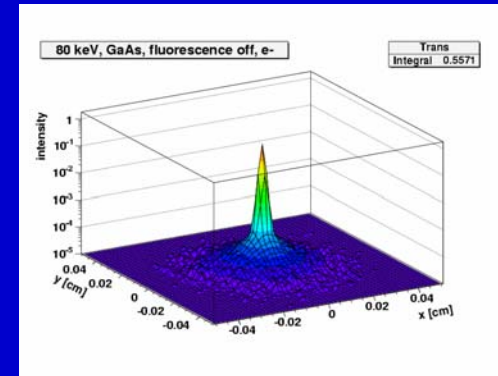
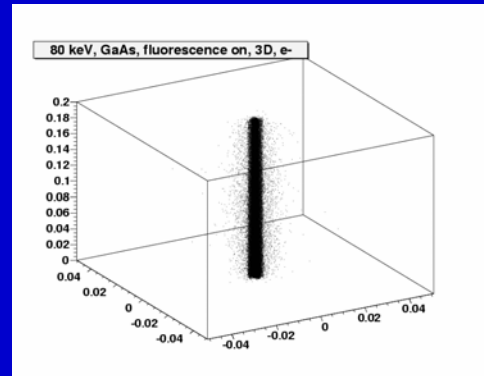




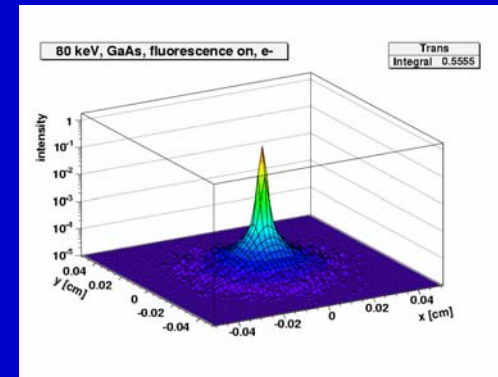
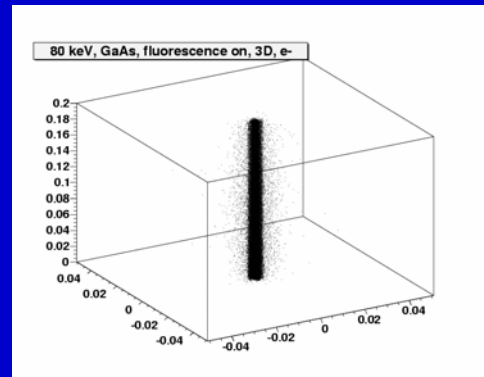
# 1) physics of X-Ray interaction with sensor material

Propagation of secondary photons:

GaAs; 80 keV  
fluorescence off

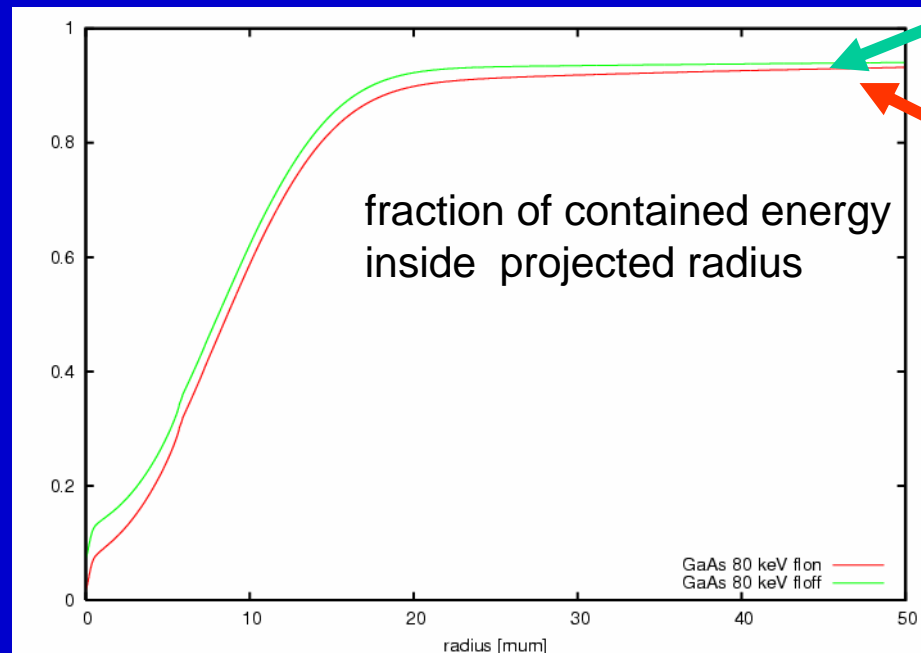


GaAs; 80 keV  
fluorescence on



# 1) physics of X-Ray interaction with sensor material

Propagation of secondary photons:



GaAs; 80 keV  
fluorescence off

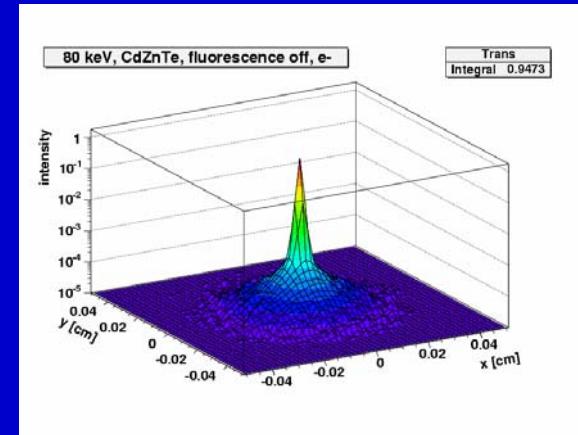
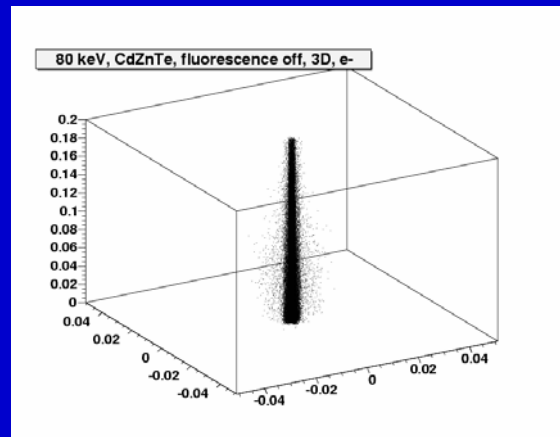
GaAs; 80 keV  
fluorescence on

Radius of 90 % of deposited Energy:  $r < 20 \mu\text{m}$  for  $E < 80 \text{ keV}$  in GaAs

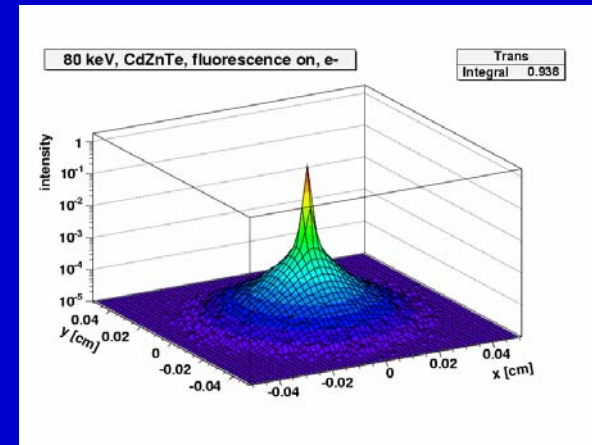
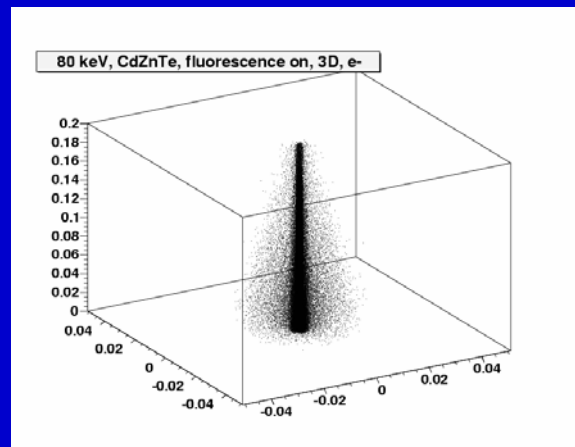
# 1) physics of X-Ray interaction with sensor material

## Propagation of secondary photons:

CdZnTe; 80keV  
fluorescence off

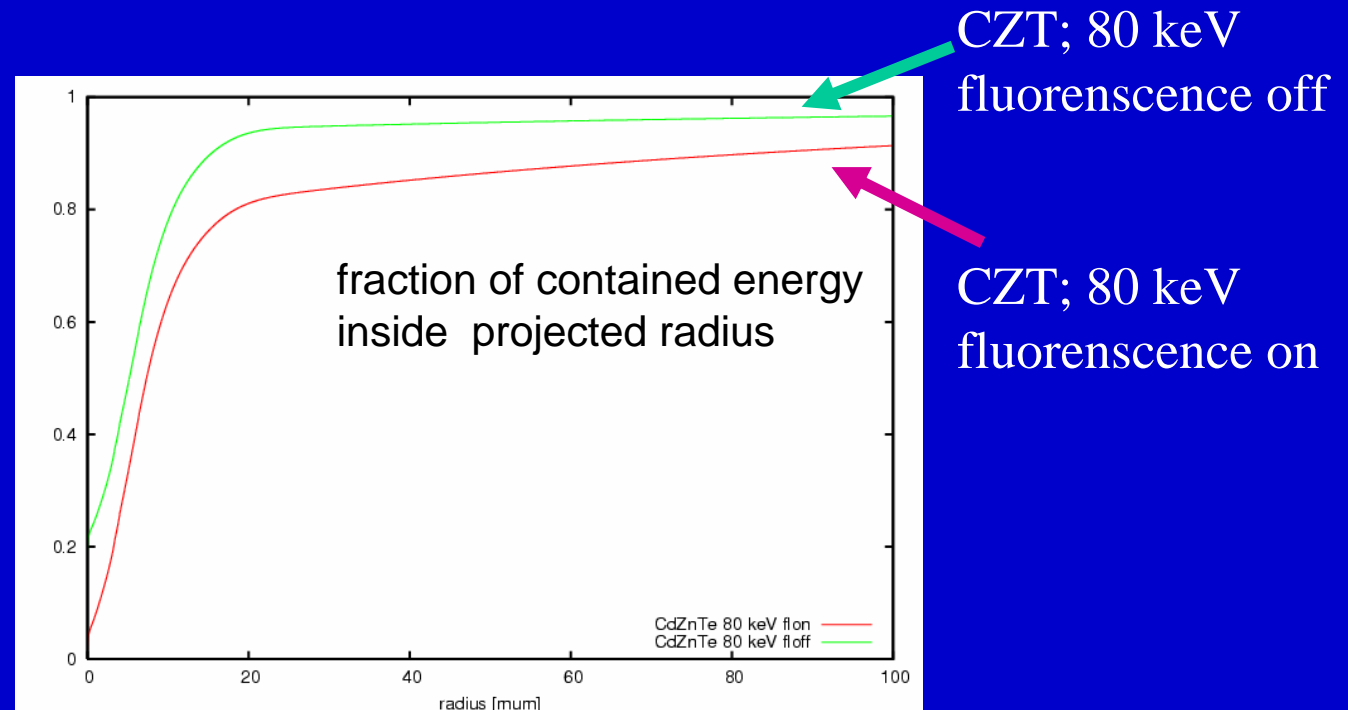


CdZnTe; 80keV  
fluorescence on



# 1) physics of X-Ray interaction with sensor material

Propagation of secondary photons:



Radius of 90 % of deposited Energy:  $r < 70 \mu\text{m}$  for  $E < 80 \text{ keV}$  in CdZnTe

## 2) propagation of charges: losses and charge sharing

Propagation of electrons and holes in semiconductor sensors:

Important parameters:

sensor bias voltage --> electrical field strength

lifetime of electrons and holes

mobility of electrons and holes

homogeneity of material

see talk by Michaela Mitschke

**result: 90 % charge radius  $r < 10 \mu\text{m}$  for  $E < 100 \text{ keV}$  in  $300 \mu\text{m CdZnTe}$**

## Spatial energy deposition and charge sharing lead to:

For counting detectors:

--> enlarged effective pixel size for low threshold  
reduced effective pixel size for high threshold  
-->see talk by Michaela Mitschke

--> reduced counting efficiency for high threshold

--> double counting for low threshold

for intergrating detectors:

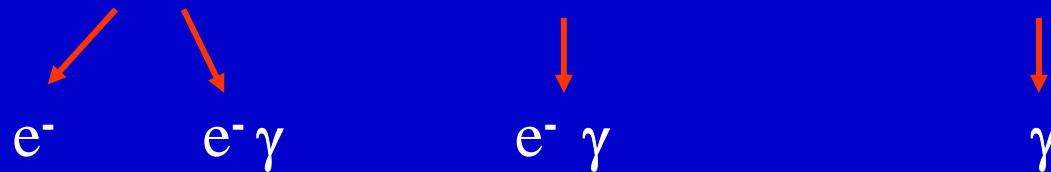
enlarged effective pixel size

no false fluence

# Summary: contributions to position resolution

real: 1) physics of X-Ray interaction with sensor material

photoabsorption. Compton scattering, Rayleigh scattering



90 % energy radius:  $r < 10 - 100 \mu\text{m}$

2) propagation of charges:

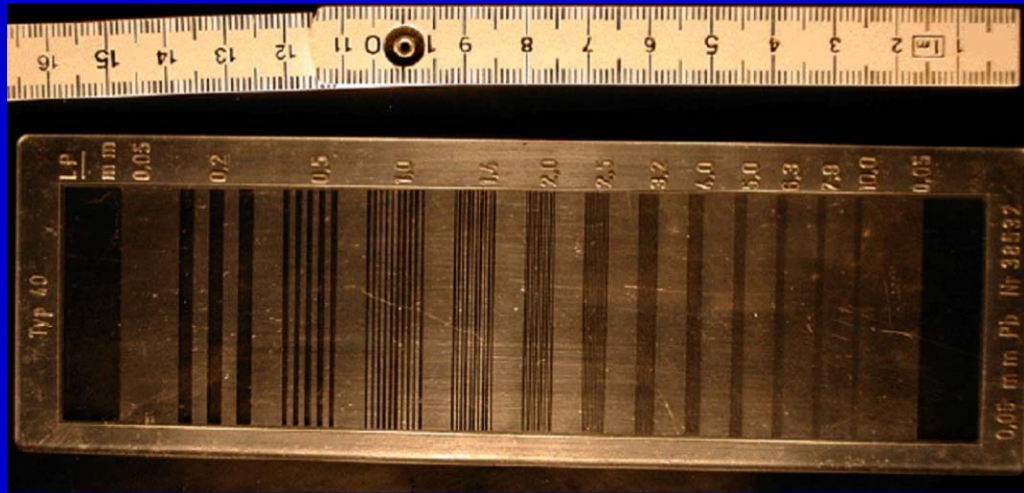
90 % charge radius:  $r < 10 \mu\text{m}$

3) finite size of read out pixels: examples:

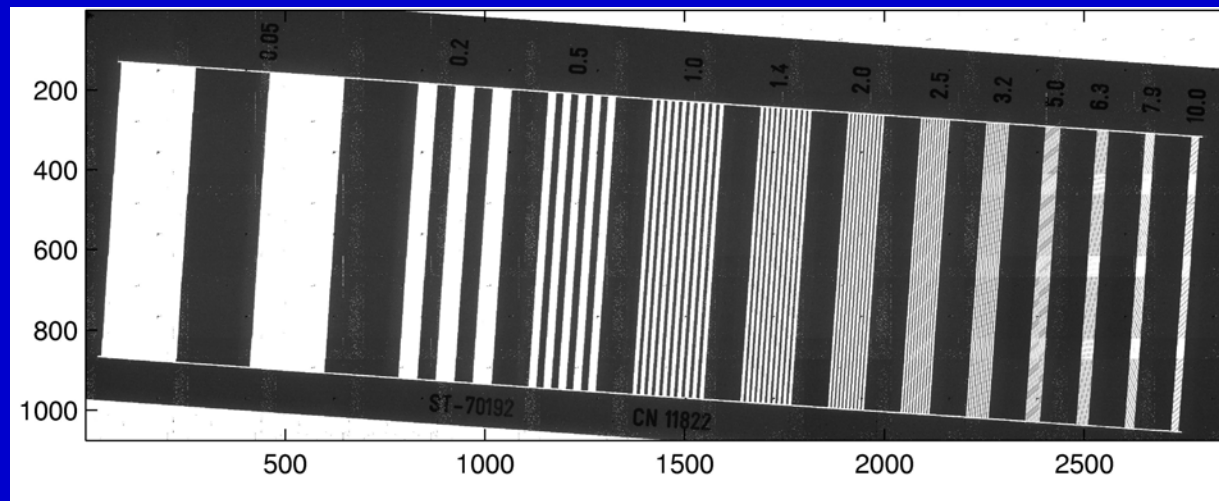
Medipix 1:  $170 \mu\text{m}$

Medipix 2:  $55 \mu\text{m}$

# Visibility of structures: Hüttner-Grid



photograph

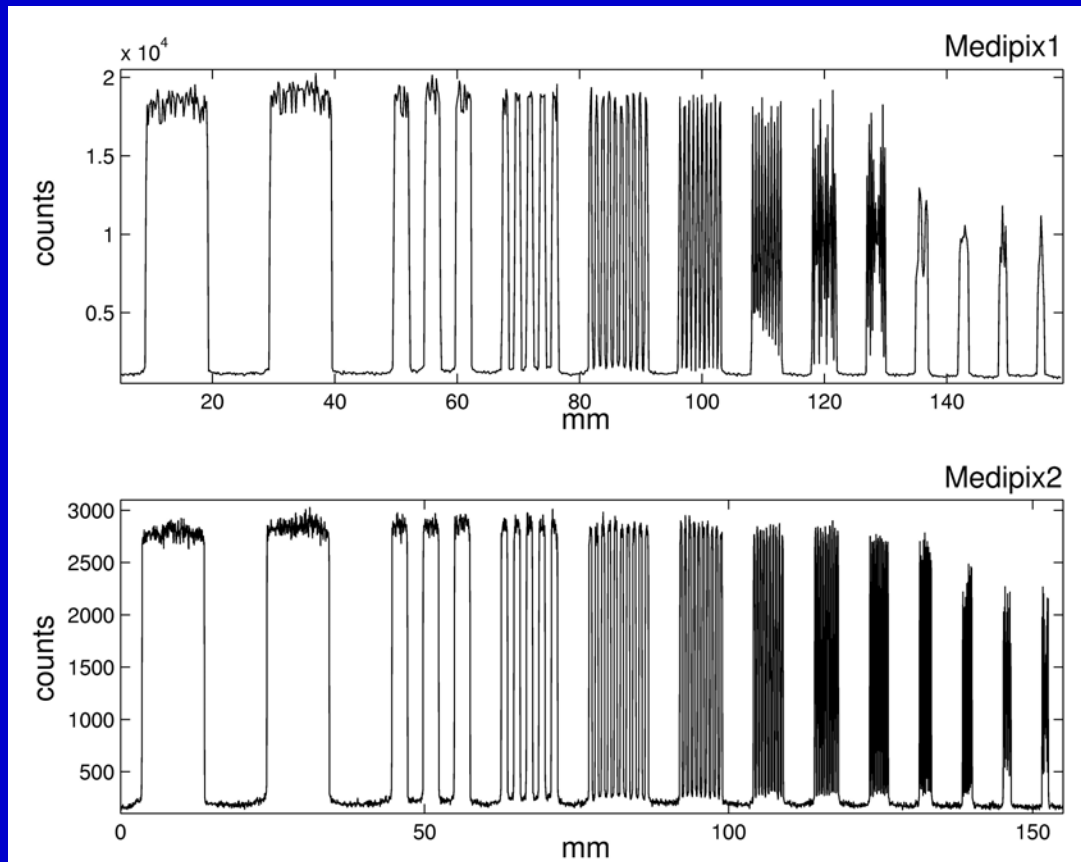


X-Ray  
Image  
(spectral)

plots taken from the phd thesis of F.Pfeiffer, Erlangen 2004

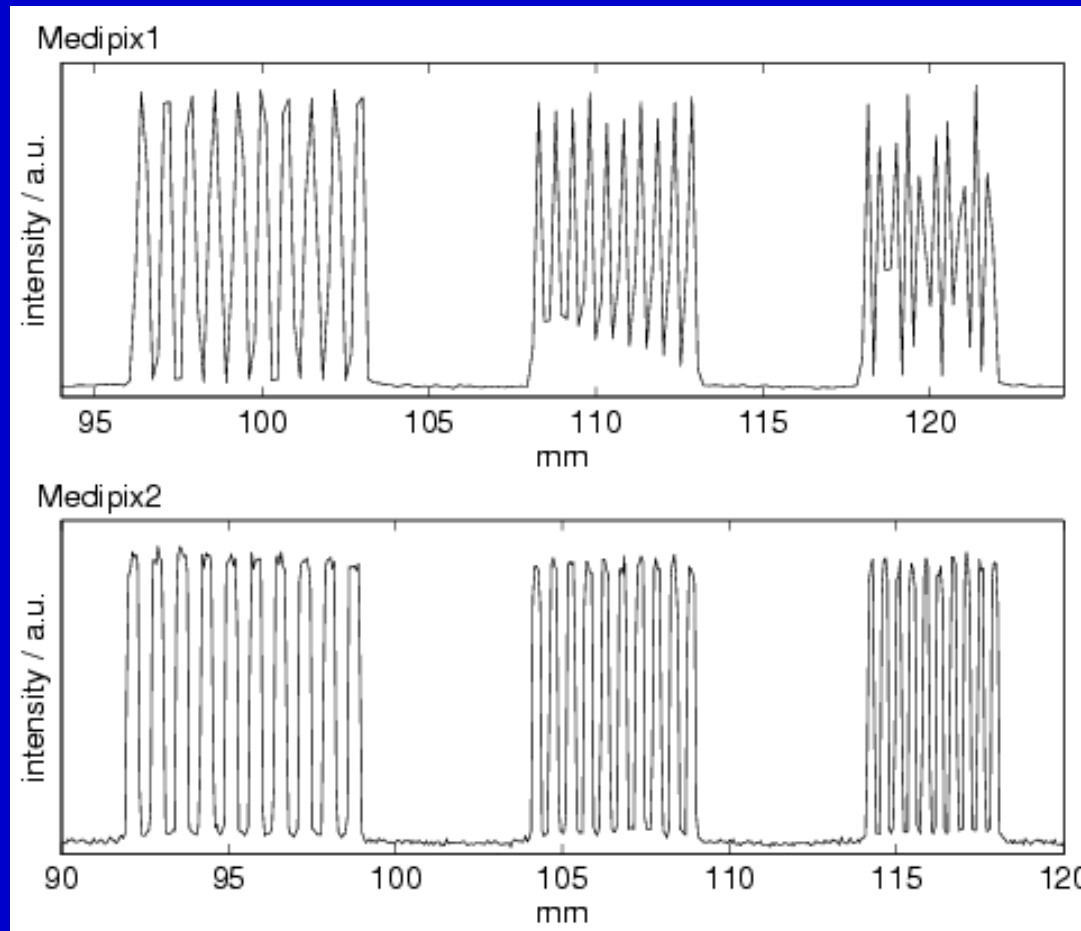


# Visibility of structures: Hüttner-Grid



plots taken from the phd thesis of F.Pfeiffer, Erlangen 2004

# Visibility of structures: Hüttner-Grid



1.4 lp/mm

2.0 lp/mm

2.5 lp/mm

# Visibility of structures: Hüttner-Grid

Sampling theorem:

structure size  $s$   
needs pixel size  $l = s/2$

spacial frequency  $f$   
needs sampling frequency:  $f_{\text{samp}} = 2f$

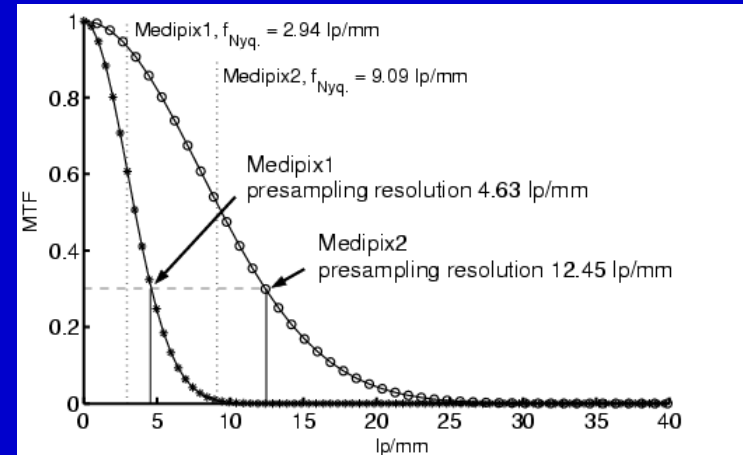
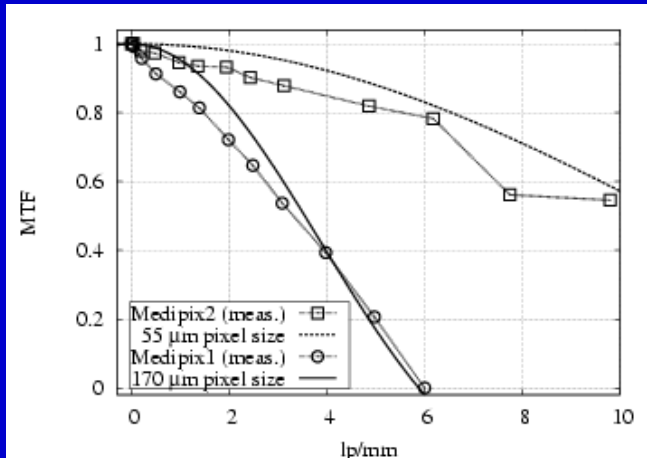
Modulation transfer function:

$$MTF(u, v) = \frac{(FT)_{out}(x, y)}{(FT)_{in}(x, y)}$$

For square pixel:

$$MTF = \frac{\sin(\pi f l)}{(\pi f l)} = \text{sinc}(\pi f l)$$

# position resolution: MTF with Medipix 1 and 2:



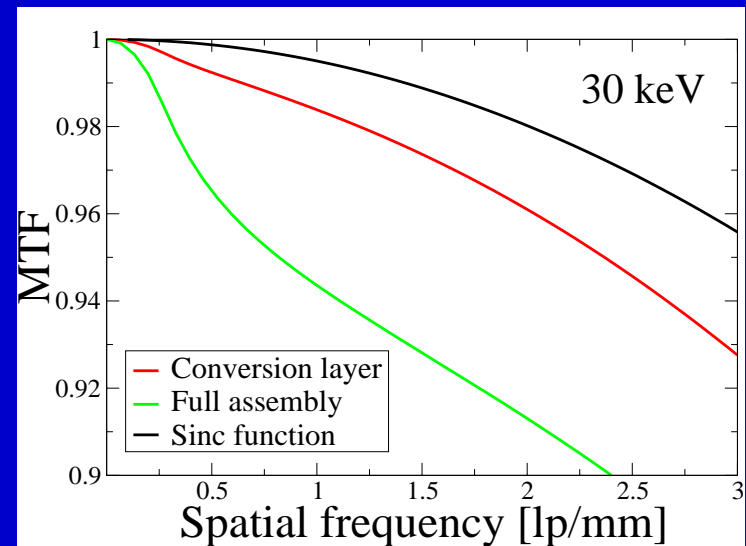
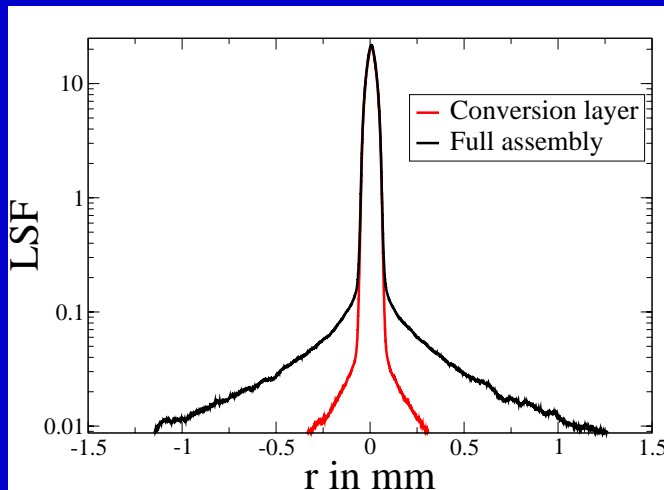
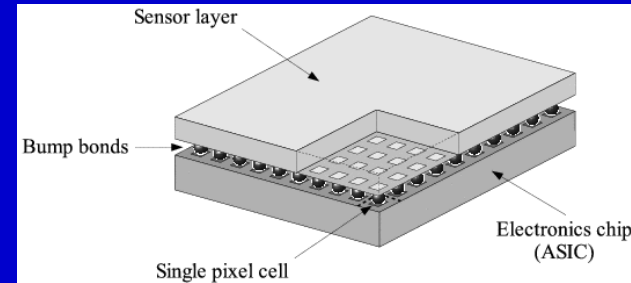
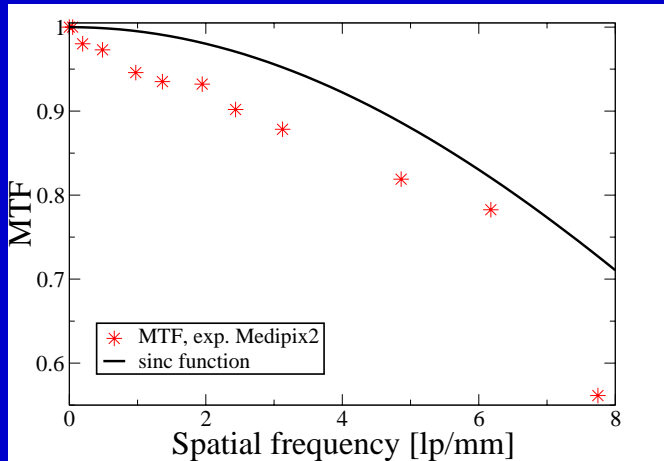
$$MTF(u, v) = \frac{(FT) out(x, y)}{(FT) in(x, y)}$$

MTF from Hüttner-Grid

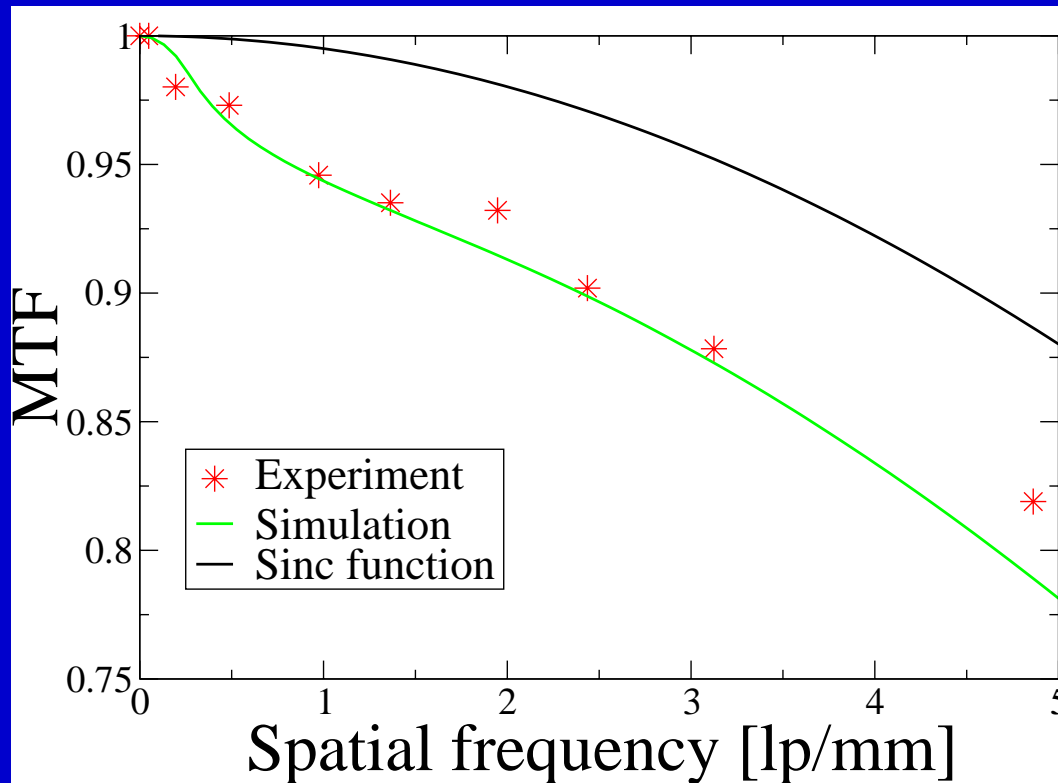
$$MTF(u, v) = (FT) PSF(x, y)$$

MTF from edge method

# position resolution: MTF and low frequency drop



# position resolution: MTF and low frequency drop



plots taken from the work of A.Korn, M.Hoheisel et al., Erlangen

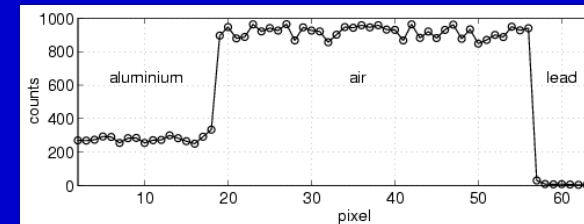
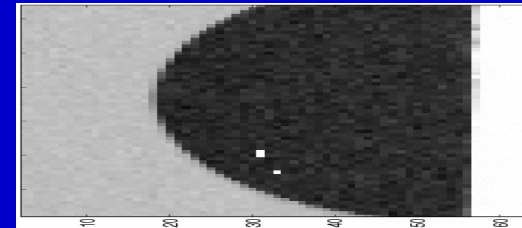
# Visibility of structures : Contrast

Contrast:

$$C = \frac{I_2 - I_1}{I_1 + I_2} = \frac{N_2 - N_1}{N_1 + N_2}$$

Signal difference to noise ratio:

$$SDNR = \frac{\Delta I}{\sigma_I} = C \sqrt{N_1 + N_2}$$

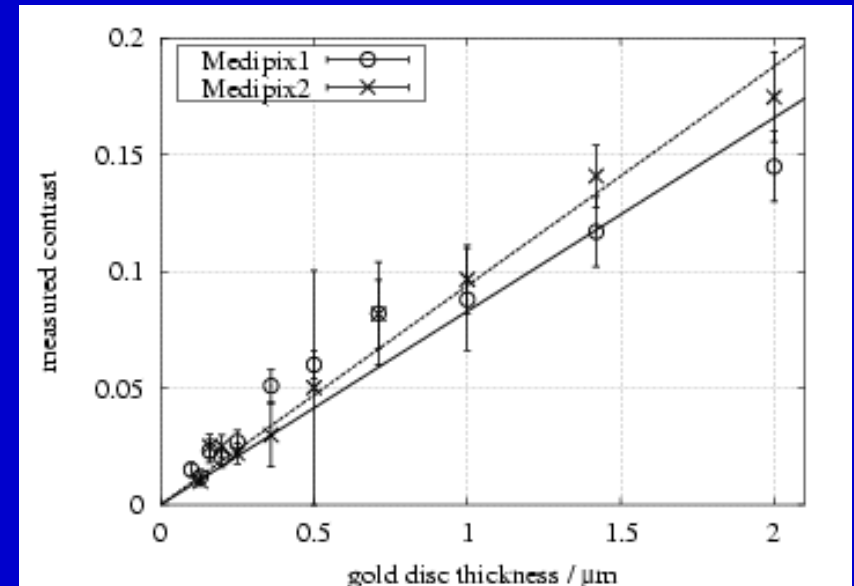
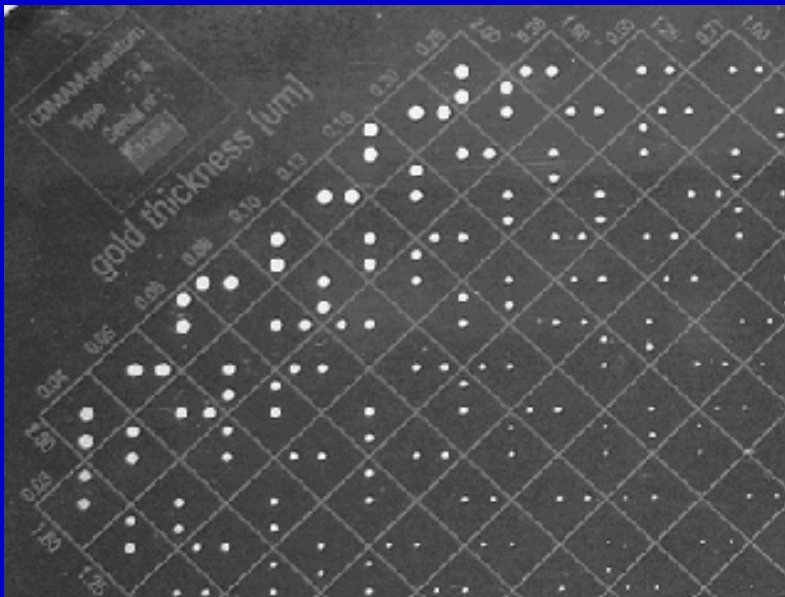


Visibility for given contrast: need large  $N = \Phi A$

--> long exposure

--> large area of structure

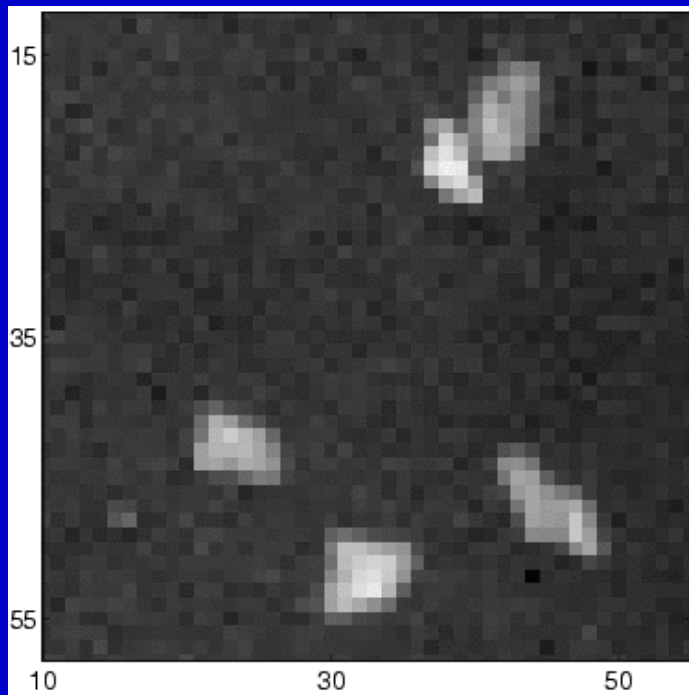
# Contrast-detail-visibility



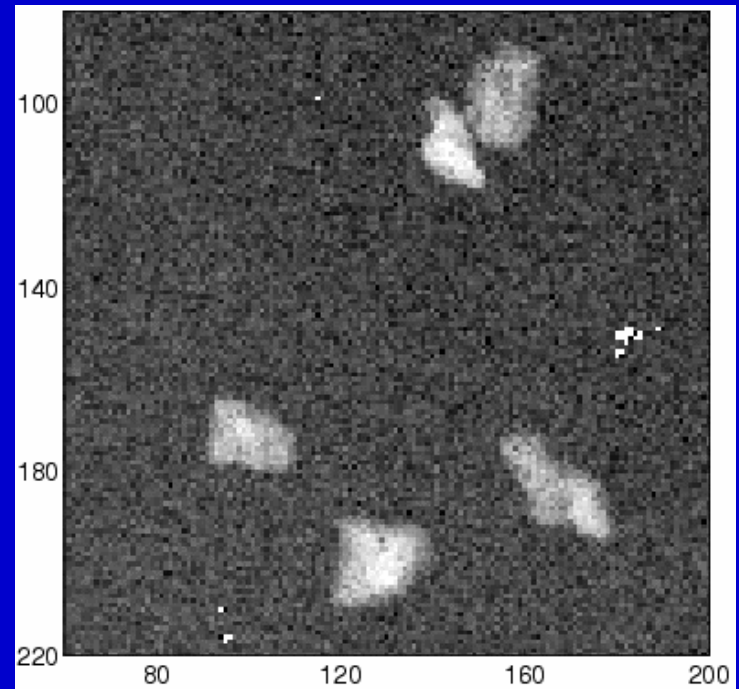
CDMAM phantom: gold disks of various size and thickness



# Contrast-detail-visibility



Medipix 1

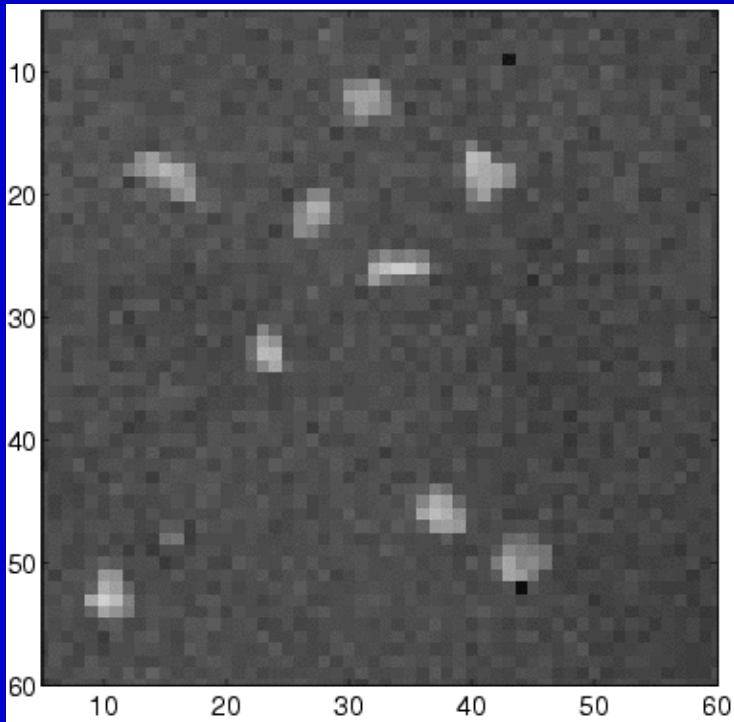


Medipix 2

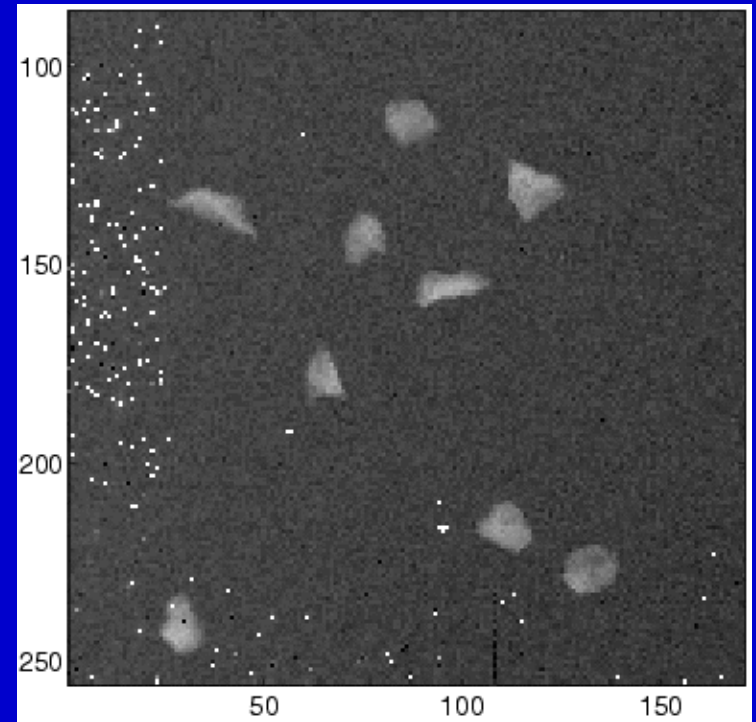
Mammographic phantom:  $\text{Al}_2\text{O}_3$  grains, size 1.1 to 1.5 mm

plots taken from the phd thesis of F.Pfeiffer, Erlangen 2004

# Contrast-detail-visibility



Medipix 1



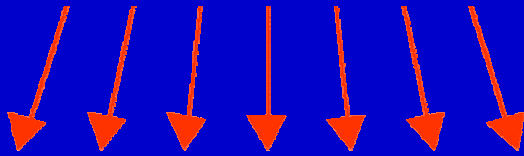
Medipix 2

Mammographic phantom:  $\text{Al}_2\text{O}_3$  grains, size .55 to .75 mm

plots taken from the phd thesis of F.Pfeiffer, Erlangen 2004

# Summary: Detector Transfer Function

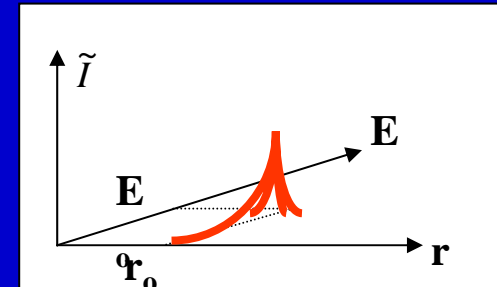
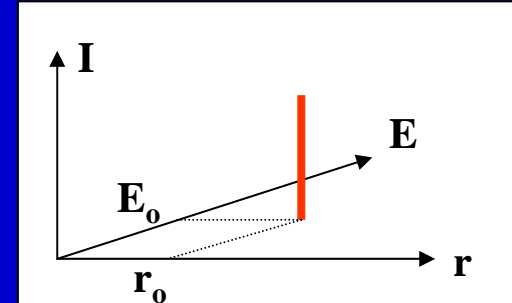
$$I(E_o, x_o, y_o)$$



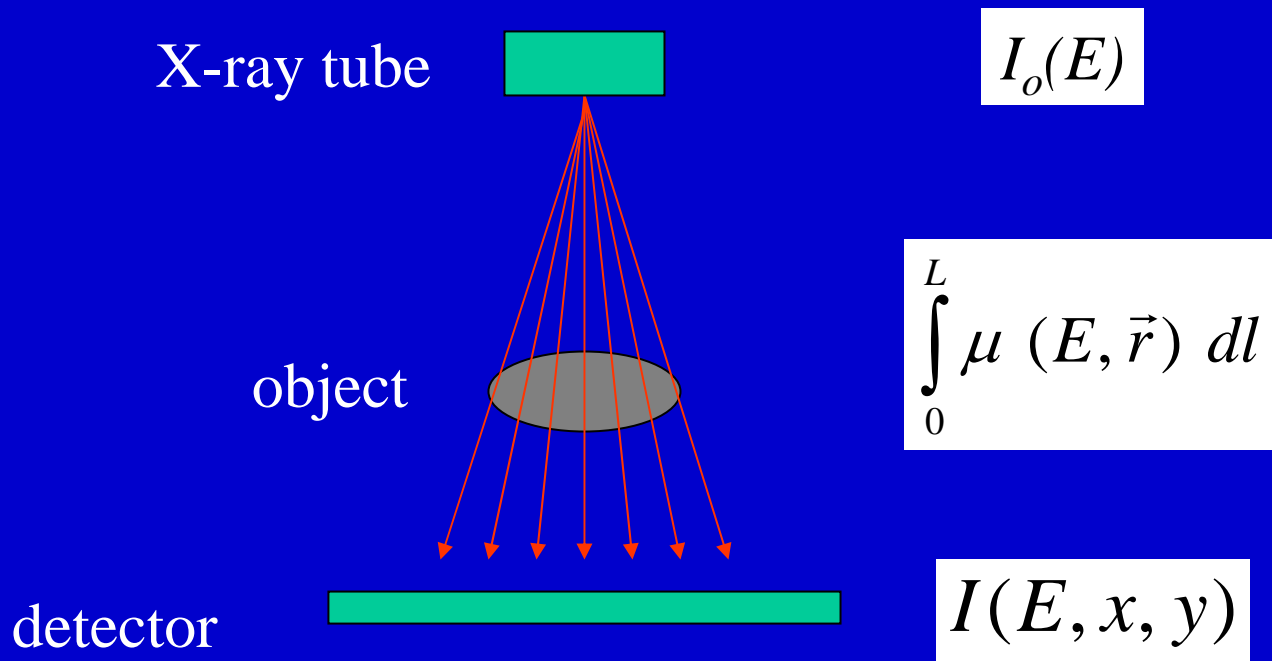
detector



$$\tilde{I}(E, x, y)$$



## B. Spectral Projective Image



# Spectral Projective Imaging

Image information:  
(energy resolving detector)

$$t(E, x, y) = -\ln \frac{I_o(E) e^{-\int_0^L \mu(E, \vec{r}) dl}}{I_o(E)} = \int_0^L \mu(E, \vec{r}) dl$$

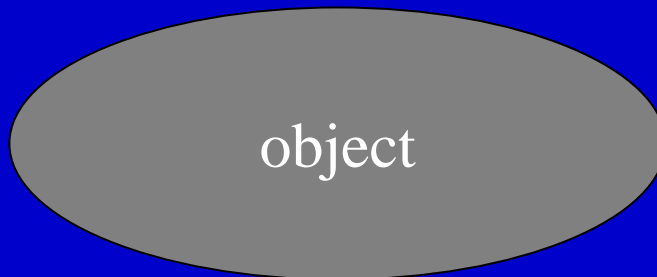
Integrating detector:

$$t_I(x, y) = -\ln \frac{\int_{E_{th}}^{E_{max}} I_o(E) E e^{-\int_0^L \mu(E, \vec{r}) dl} dE}{\int I_o(E) E dE}$$

Counting detector:

$$t_C(x, y) = -\ln \frac{\int_{E_{th}}^{E_{max}} I_o(E) e^{-\int_0^L \mu(E, \vec{r}) dl} dE}{\int I_o(E) dE}$$

# Spectral projective X-Ray Image Information

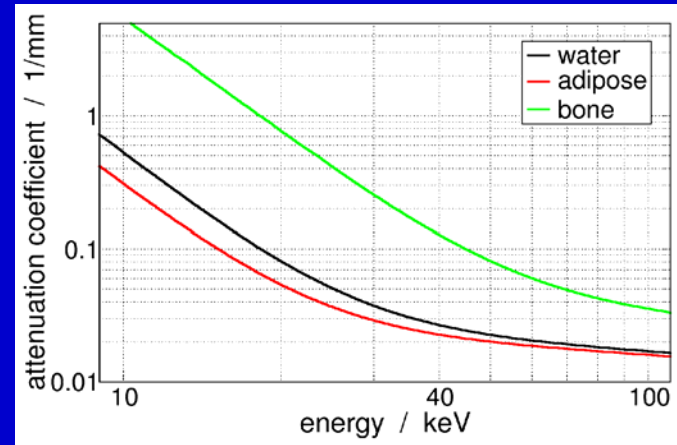
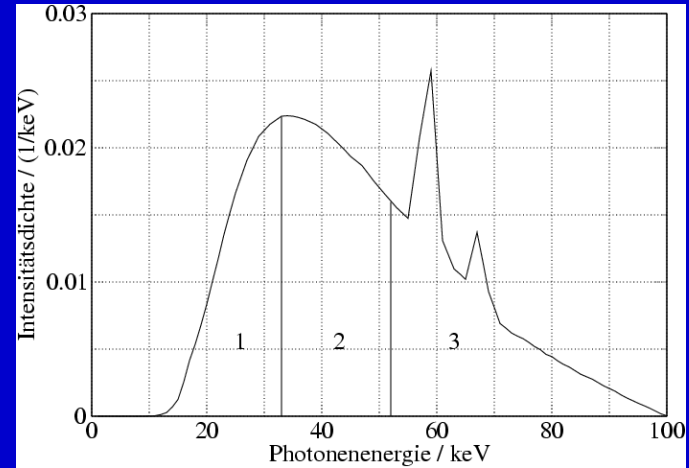
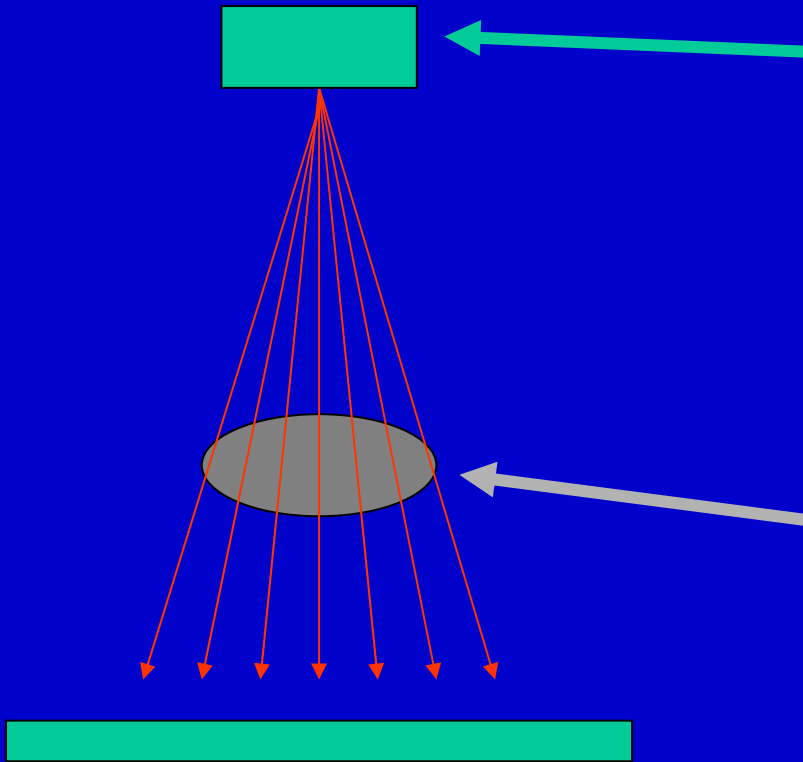


$$\int_0^L \mu(E, \vec{r}) dl$$

How to make use of the energy information:

- 1) single image for each energy --> too much noise per image !
- 2) contrast energy weighted image
- 3) material reconstruction

# Spectral sensitivity



## 2. Contrast energy weighted image

Contrast:

$$C(E_i) = \frac{I_2(E_i) - I_1(E_i)}{I_2(E_i) + I_1(E_i)} = \frac{e^{-\mu_1 d_1} - e^{-\mu_2 d_2}}{e^{-\mu_1 d_1} + e^{-\mu_2 d_2}} = w_i$$

By taking

$$I = \sum I_i w_i$$

SDNR=max :

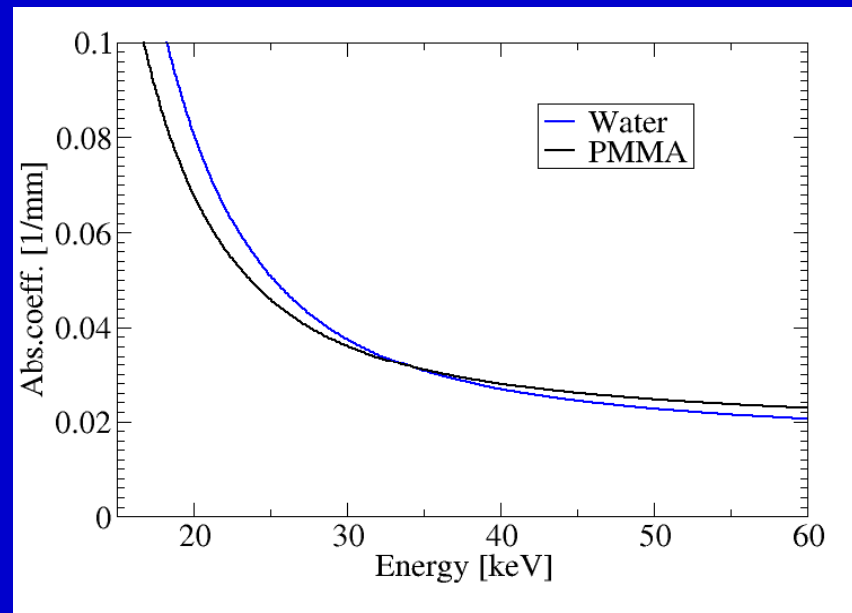
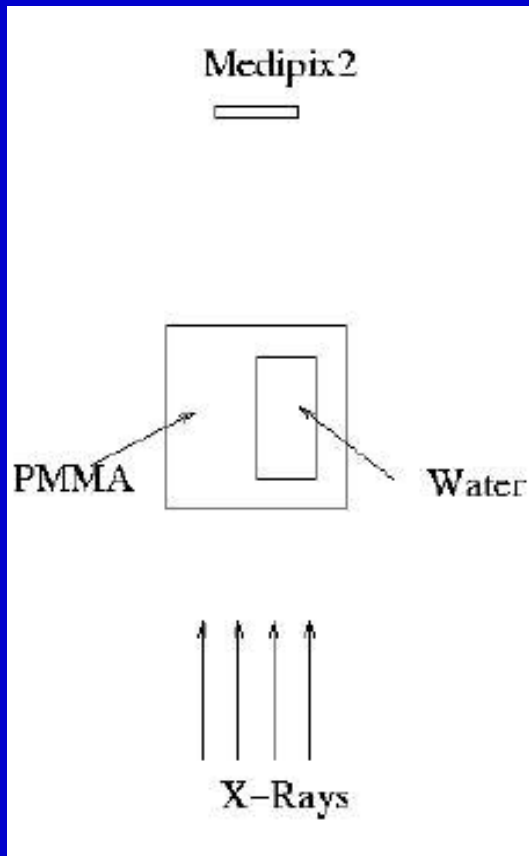
$$SDNR = \frac{I_2 - I_1}{\sigma} = \frac{\sum (I_{2,i} - I_{1,i}) w_i}{\sqrt{\sum (I_{2,i} + I_{1,i}) w_i^2}}$$

Quality:

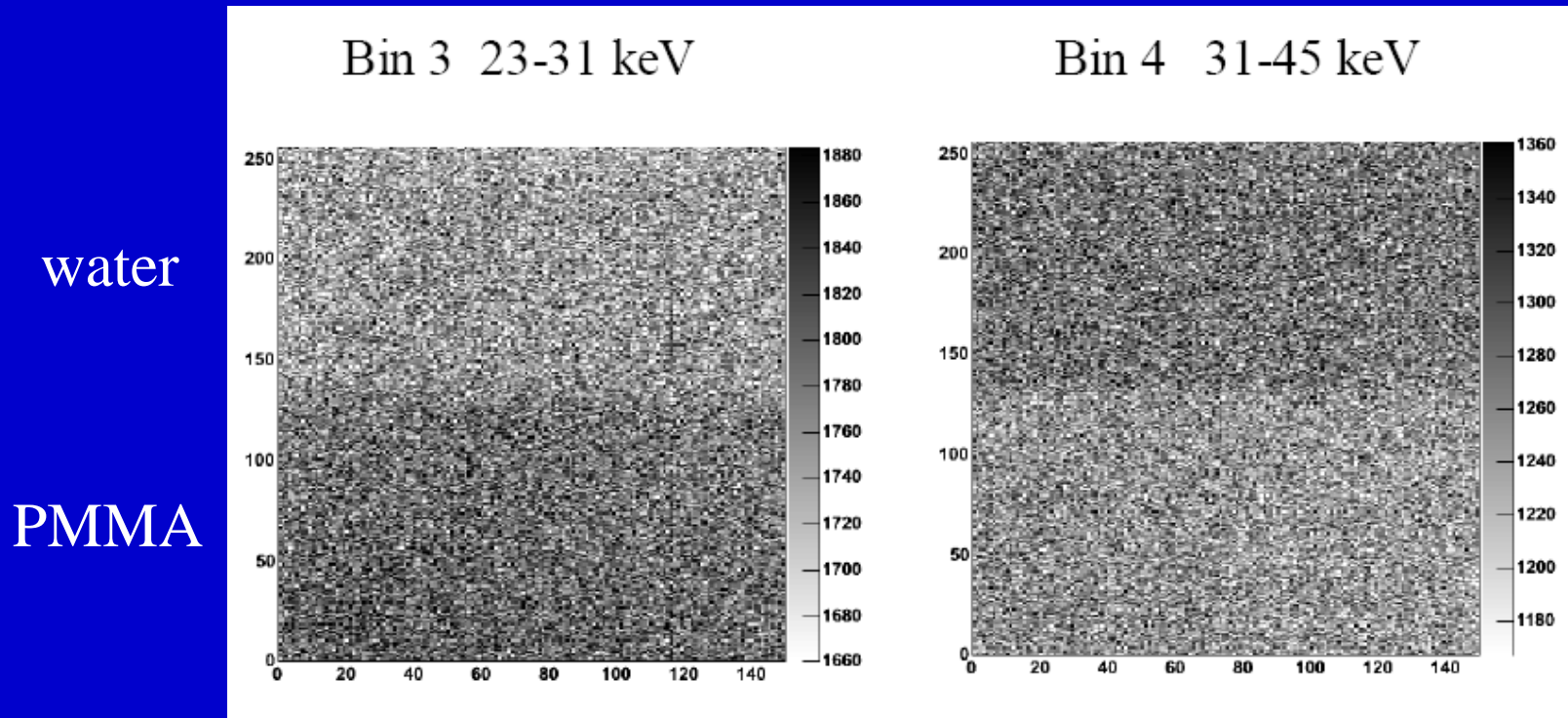
$$FOM = \frac{SDNR^2}{dose}$$



# Examples of energy weighted images



# Images in energy intervals



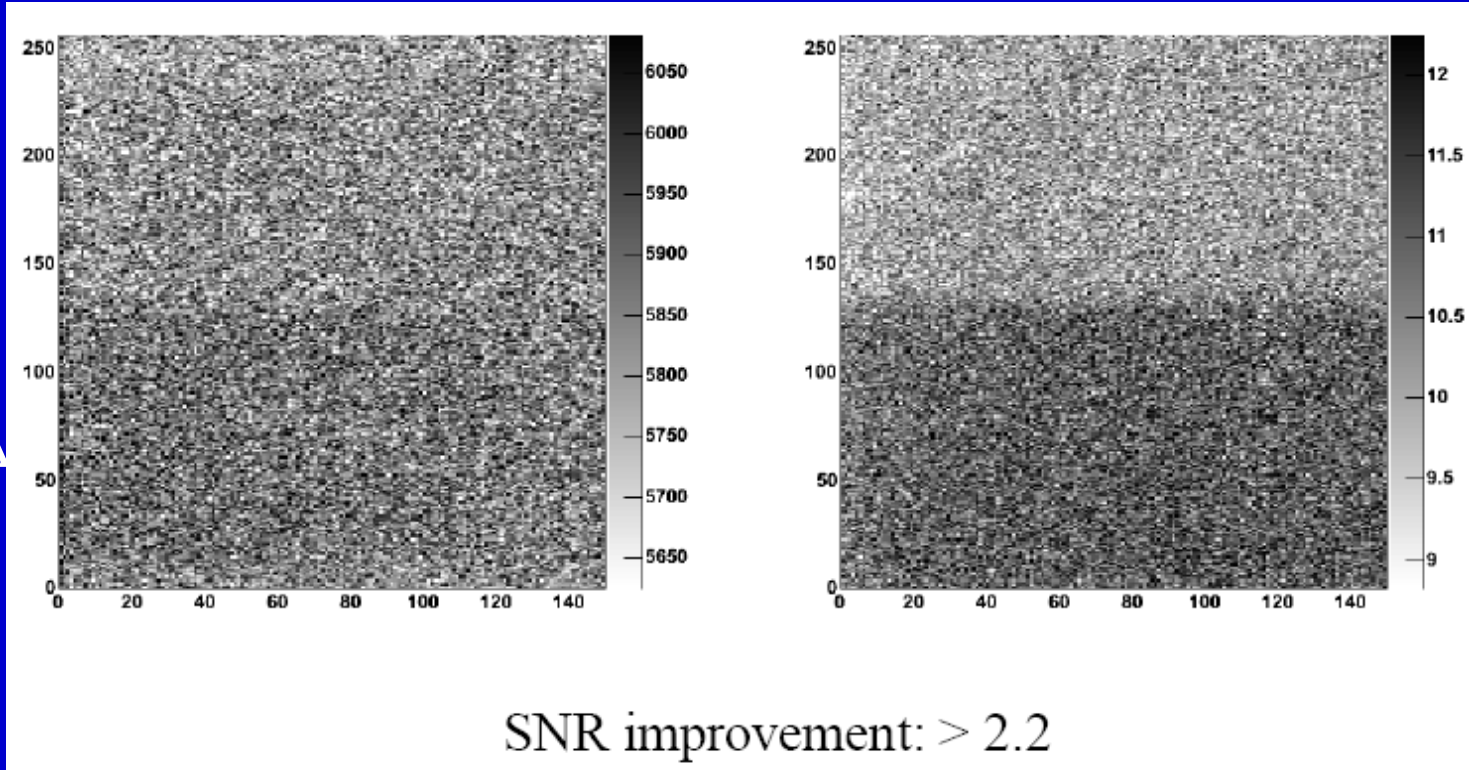
60 kV, W anode ,2mm Al filter, 300  $\mu$  Si, 150 V

plots taken from the diploma thesis of J.Karg, Erlangen 2004

# Examples of energy weighted images

water

PMMA



photon counting image

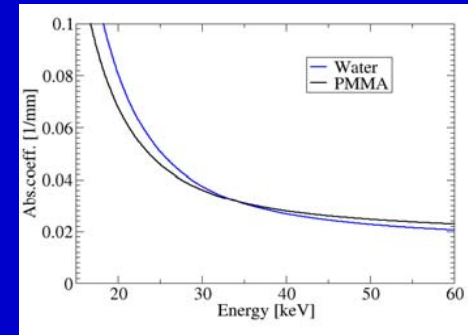
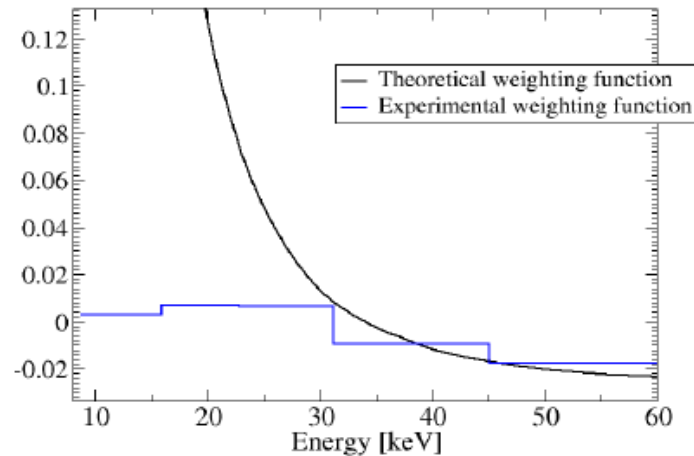
energy weighted image

# Examples of energy weighted images

- Weighting Function calculated from image:

$$w = \frac{(I_1 - I_2)}{(I_1 + I_2)}$$

- Large discrepancies compared to theoretical weighting function (ideal detector)



Problem with Medipix 2: bad energy resolution due to broad energy deposition and charge sharing !!  
--> Medipix 3

### 3 .Material reconstruction

$$t(E) = -\ln T(E) = -\ln \frac{N(E)}{N_o(E)} = \sum_{j=1}^m \left( \frac{\mu(E)}{\rho} \right)_j p_j$$

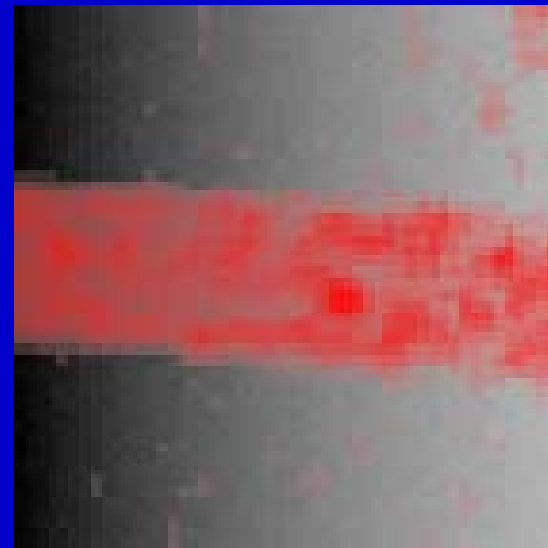
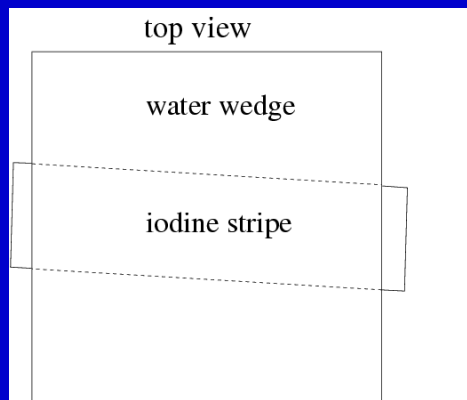
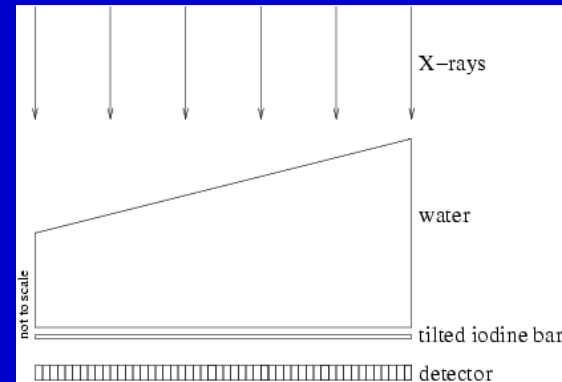
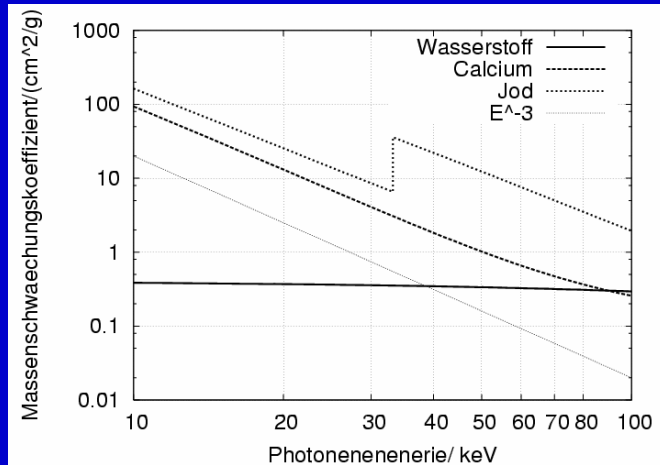
$$p_j = (\rho d)_j$$

For energy bin  $i$  :

$$t_i = -\ln T_i = -\ln \frac{N_i}{N_{io}} = \sum_{j=1}^m \left( \frac{\mu}{\rho} \right)_{ij} p_j = M_{ij} p_j$$

Method: determine for given material matrix  $M$   
the amount of material  $p$   
which fits best to measured image  $t$

# Simulated examples for material reconstruction



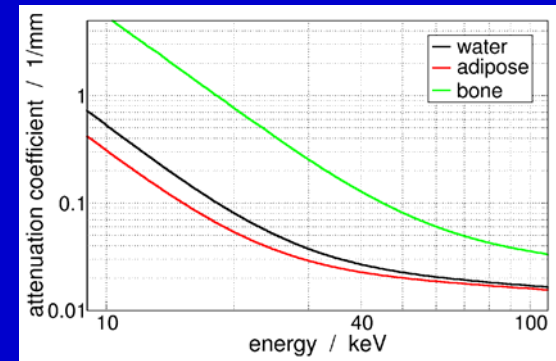
# Material reconstruction in medical imaging

Medical imaging:

Most of the contrast is due to density variations:

Atten. coeff. of different „materials“  
all have the same energy dependence

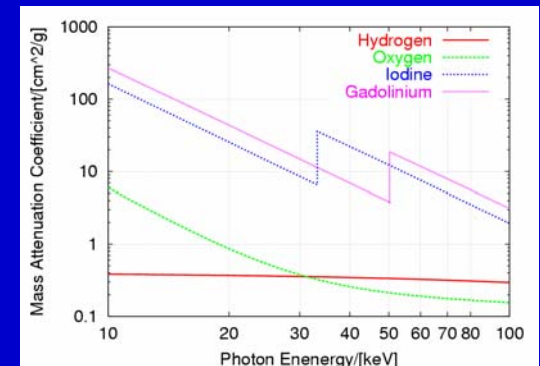
Normal contrast agents have high **density**.



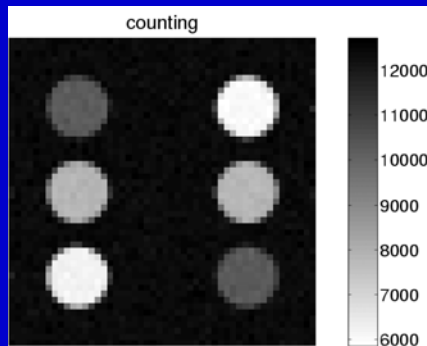
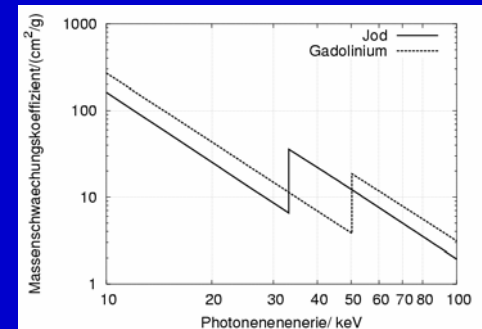
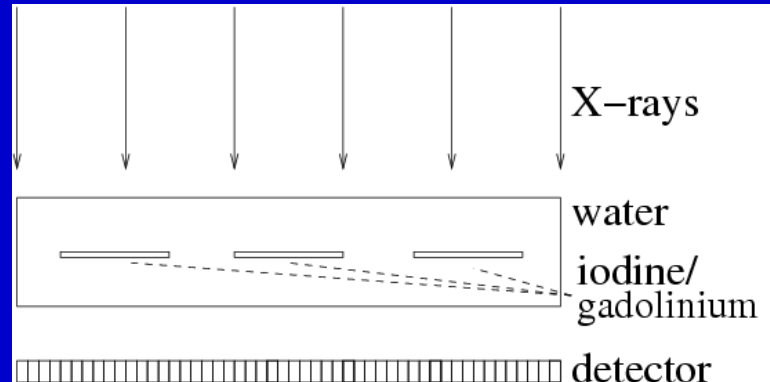
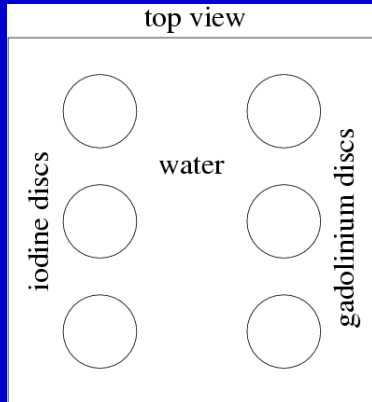
New concept:

Contrast agent has different **energy** behaviour

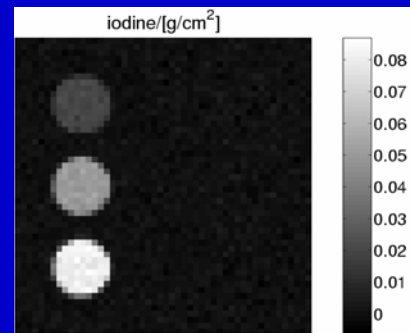
→ Quantitative agent reconstruction



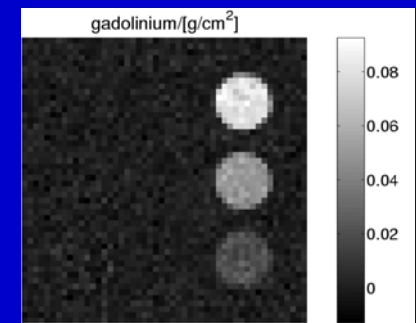
# Simulated examples for material reconstruction



Photon counting



Iodine image



Gadolinium image



# Material reconstruction for broad energy bins:

$$T_{eff} = \frac{\int_{E_1}^{E_2} T(E) S(E) dE}{\int_{E_1}^{E_2} S(E) dE} = \frac{\int_{E_1}^{E_2} \exp\left(-\frac{\mu(E)}{\rho} p\right) S(E) dE}{\int_{E_1}^{E_2} S(E) dE}$$

$$\mu_{eff} = -\frac{1}{p} \ln T_{eff}$$

## C. Tomographic Images

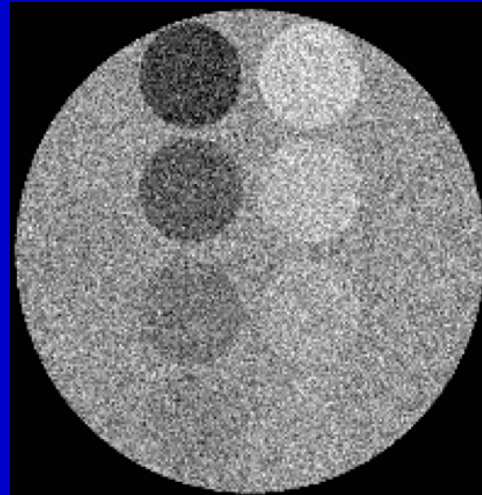
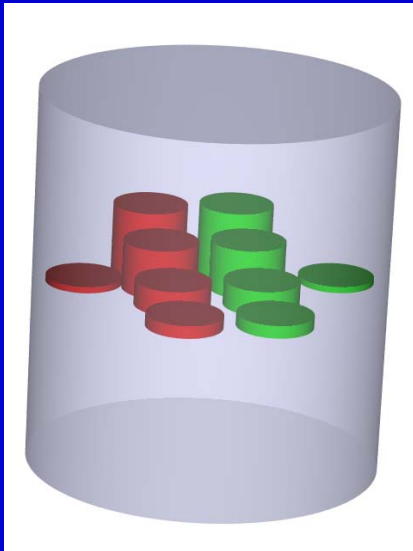
CT-imaging:

$$t(x, \theta) = -\ln T(x, \theta) = -\ln \frac{N}{N_o}(x, \theta)$$

→  $\tilde{\mu}(\vec{r}) = \langle \mu(E, \vec{r}) \rangle_{Det}$

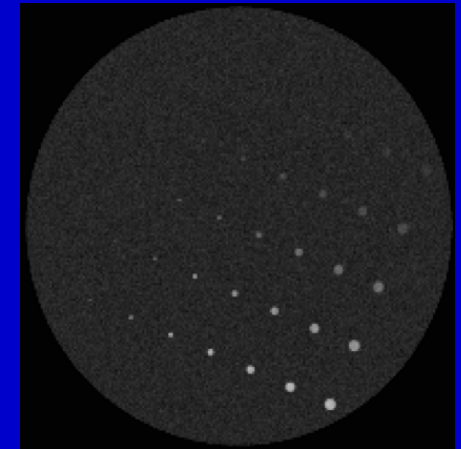
## C. Tomographic Images

Simulated photon counting images:



35 keV, Mo anode

low contrast phantom:  
water and fat disks in breast tissue

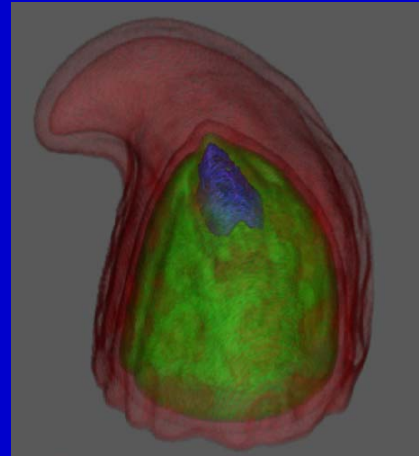
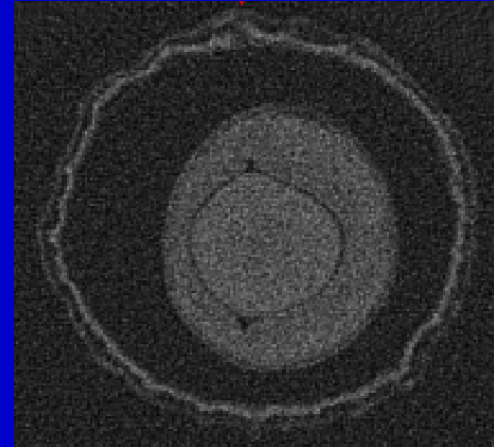
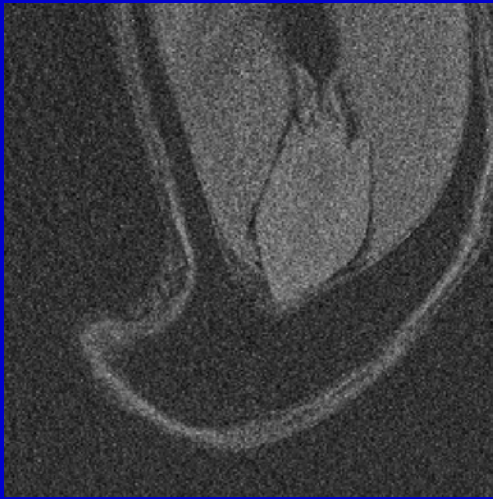


35 keV, Mo anode

high contrast:  
calcium disks in  
breast tissue

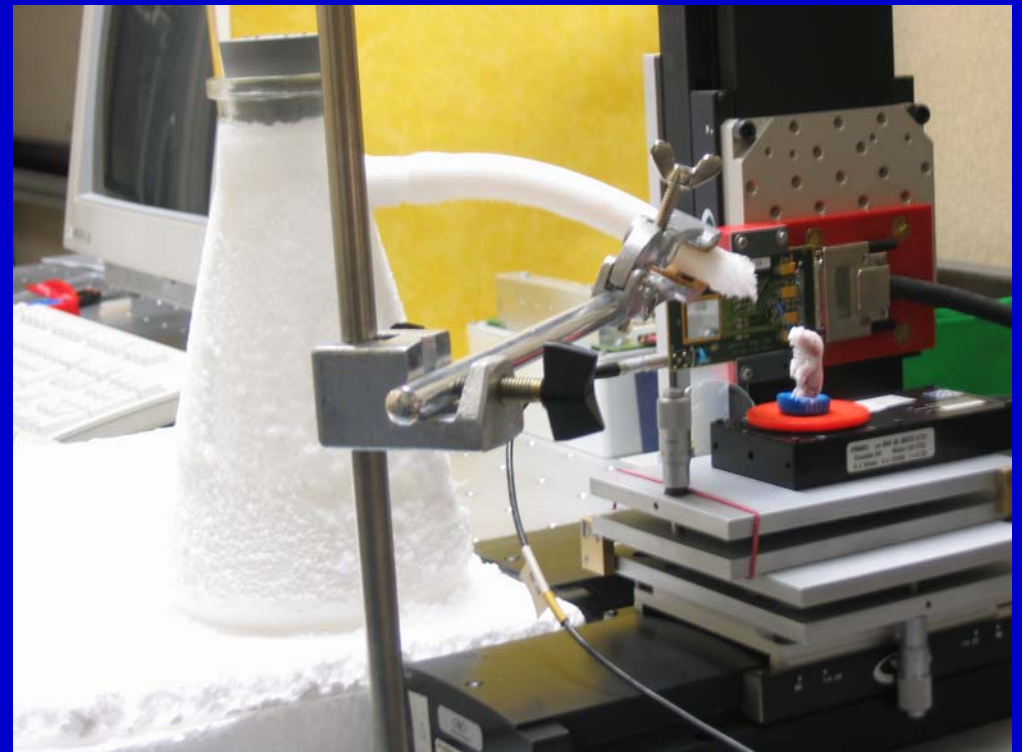
## C. Tomographic Images

CT image of a peanut  
with Medipix 2



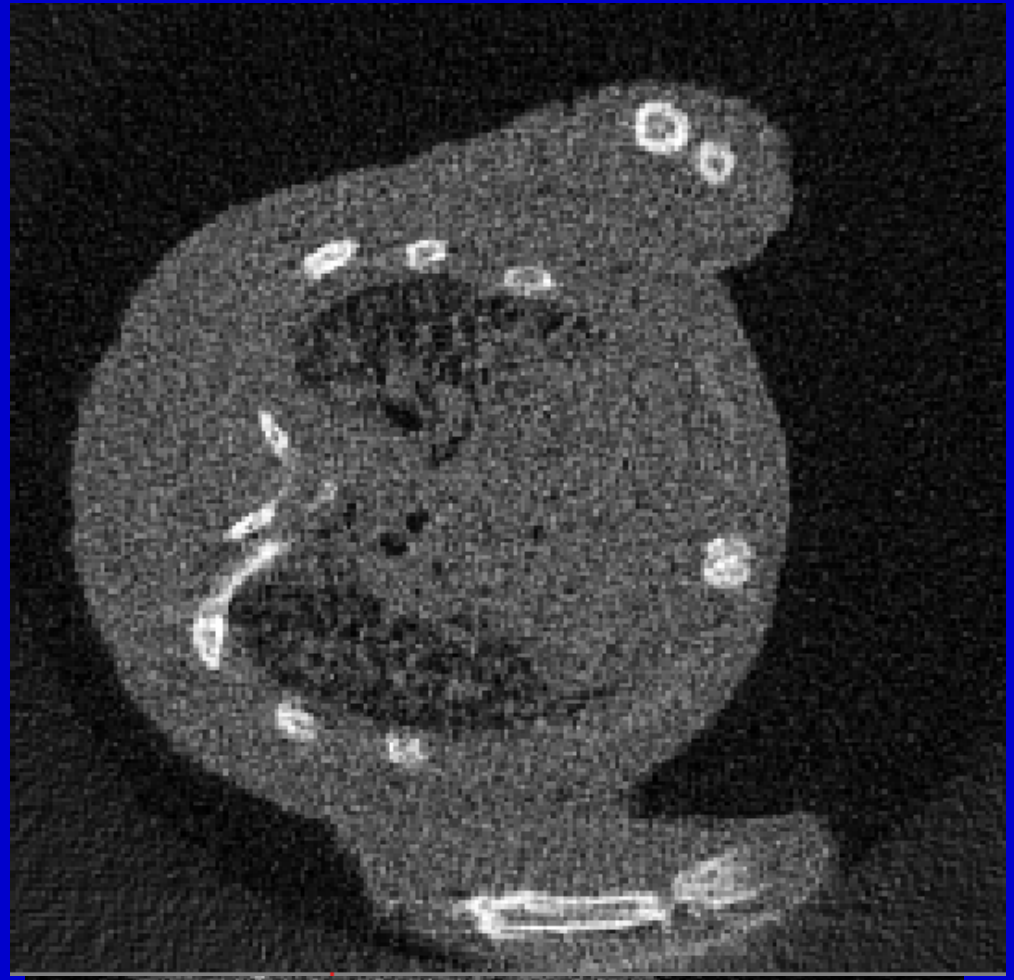
## C. Tomographic Images

CT image of a mouse  
with Medipix 2



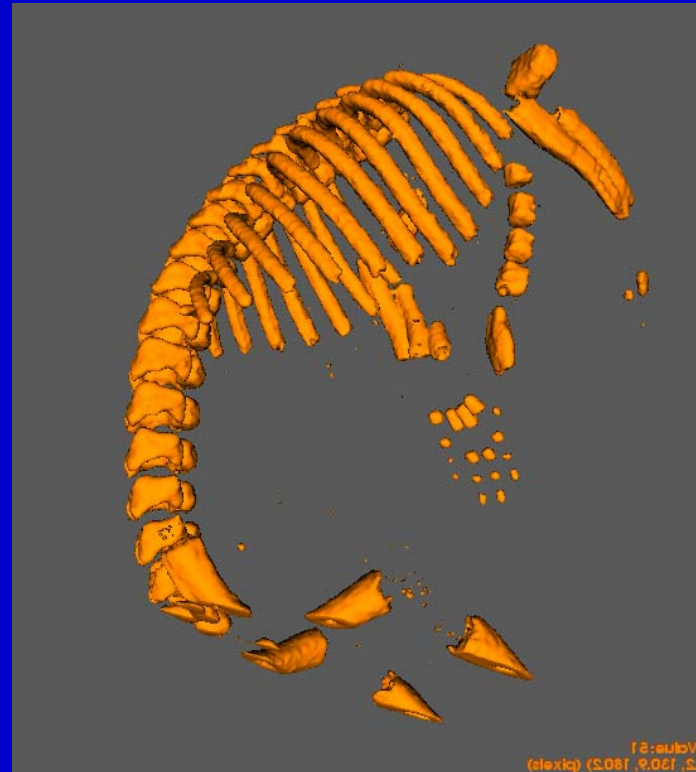
## C. Tomographic Images

CT image of a mouse  
with Medipix 2



## C. Tomographic Images

CT image of a mouse  
with Medipix 2



plots taken from the work of D.Niederloehner, Erlangen 2005

## C. Tomographic Images

CT-imaging:





## C. Tomographic Images

CT-imaging:



## C. Tomographic Images

Energy sensitive CT-imaging:

$$t_i(E, x, \theta) = -\ln T_i(E, x, \theta) = -\ln \frac{N_i}{N_{io}}(E, x, \theta)$$

$$\longrightarrow \mu(E, \vec{r}) \longrightarrow \langle \mu(\vec{r}) \rangle_{opt}$$

Many thanks  
to my students  
for their work


The End

## C. Tomographic Images

CT-imaging:

1. Take logarithm:  $\eta_\theta(t) = \ln \frac{I_0}{I_\theta(t)}$
2. Filter with kernel:  $\zeta_\theta(t') = \int_{-\infty}^{\infty} \eta_\theta(t) h(t - t') dt$
3. Back project:  $f(x, y) = \int_0^\pi \zeta_\theta(x \cos \theta + y \sin \theta) d\theta$

$$t(x, \theta) = -\ln T(x, \theta) = -\ln \frac{N}{N_o}(x, \theta)$$

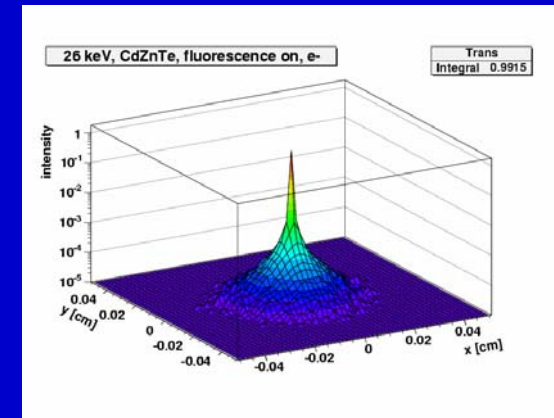
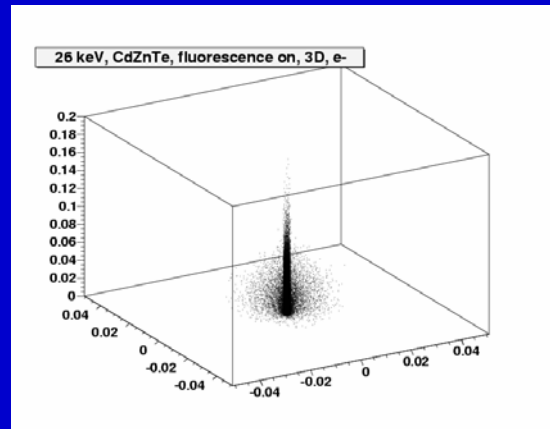
  $\tilde{\mu}(\vec{r}) = \langle \mu(E, \vec{r}) \rangle_{Det}$

plots taken from the diploma: thesis of J.Karg, Erlangen-2004

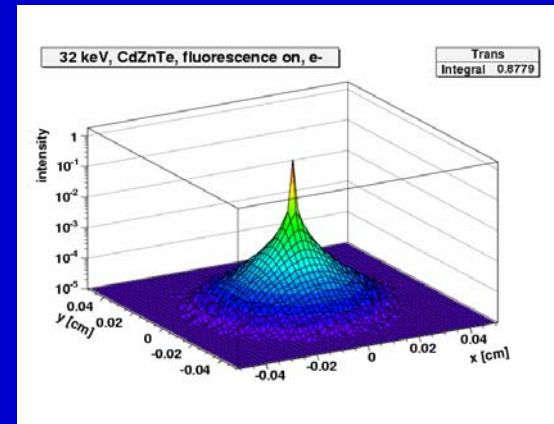
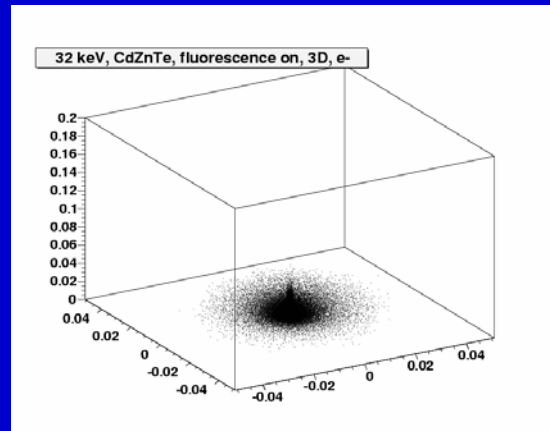
# 1) physics of X-Ray interaction with sensor material

## Propagation of secondary photons:

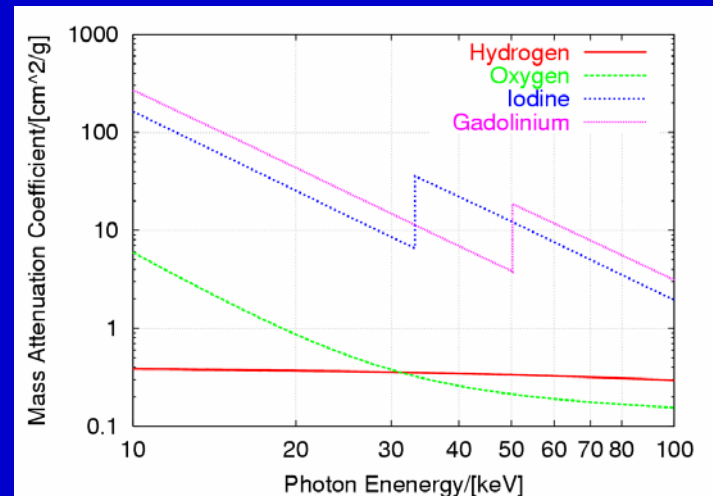
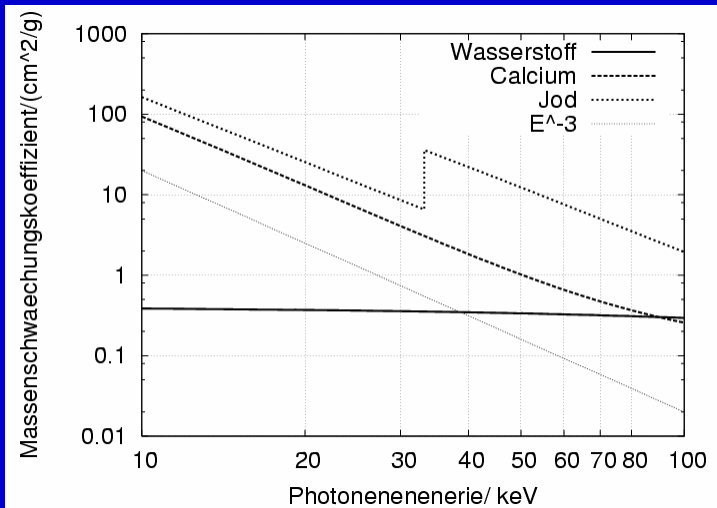
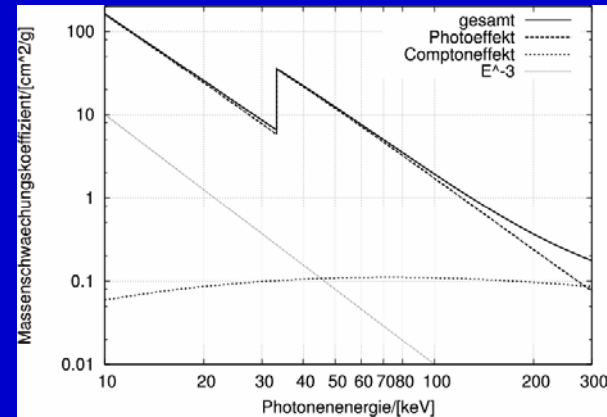
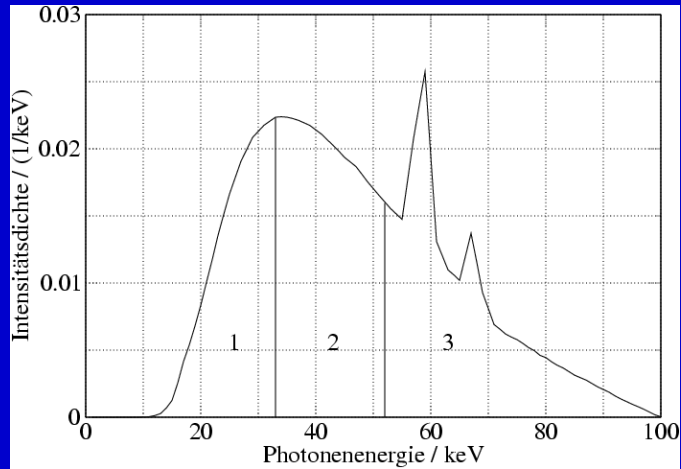
CZT  
26 keV



CZT  
32 keV



# Spectral attenuation coefficients





$$\int_{E_{th}}^{E_{max}} \int_0^L \mu(E, \vec{r}) dl dE = \ln \frac{\int I(E, \vec{r}) dE}{\int I_o(E) dE} \quad \text{page} \quad \int_0^L \mu(E, \vec{r}) dl = \ln \frac{I(E, \vec{r})}{I_o(E)}$$

$$\int_0^L \mu(E, \vec{r}) dl = \ln \frac{I(x)}{I_o} = \ln \frac{\int I(E, x) dE}{\int I_o(E) dE}$$

$$\int_0^L \mu(E, \vec{r}) dl = \ln \frac{I(E, \vec{r})}{I_o(E)}$$

$$P(x) = \ln \frac{I(x)}{I_o} = \int_0^L \mu(\vec{r}) dl$$

$$P(x) = \ln \frac{I(x)}{I_o}$$

$$\mu(E, \vec{r})$$

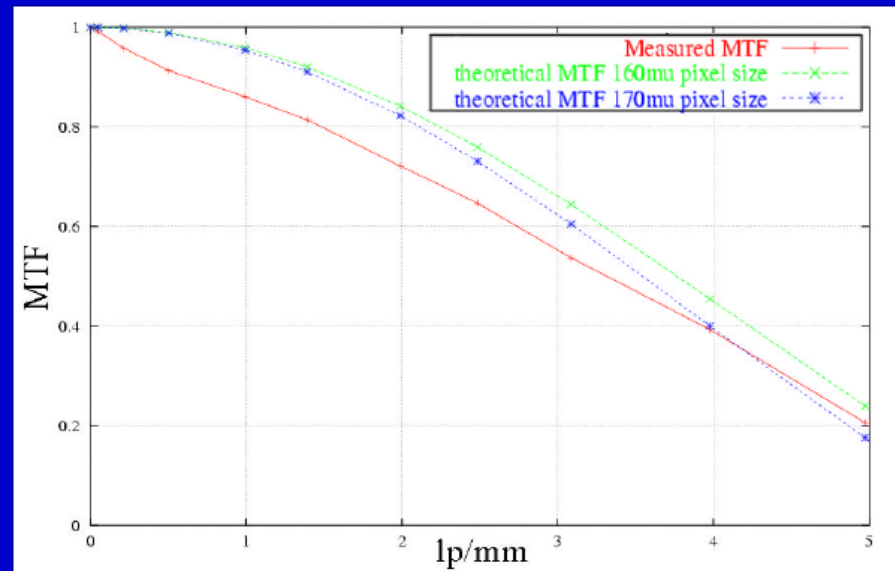
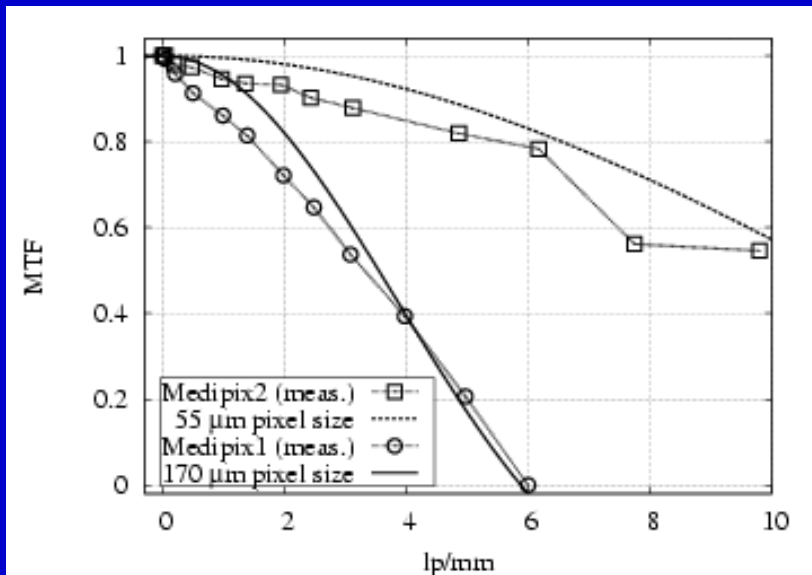
$$\ln \frac{I(E, x)}{I_o(E)} = \frac{\int_{E_{th}}^{E_{max}} I_o(E) e^{\int_0^L \mu(E, \vec{r}) dl} dE}{\int I_o(E) dE} = \ln \frac{\int I(E, \vec{r}) dE}{\int I_o(E) dE}$$

$$\int_0^L \mu(E, \vec{r}) dl$$

$$I_o(E) e^{\int_0^L \mu(E, \vec{r}) dl} = I(E)$$

$$I(x) = I_o e^{\int_0^L \mu(\vec{r}) dl}$$

# position resolution: MTF with Medipix 1 and 2:



Medipix 1